

Recap

- Description of defects in crystalline materials
 - Higher dimensional defects - Various Interfaces
 - One-dimensional defects - Dislocations
 - Point defects
- Vacancies in a metallic crystal
 - Entropy of configuration leads to eqm. conc.
 - Temperature dependence of this conc.

Defects in Ionic/Covalent Materials

Additional Reading:
Section 5.5 and 5.6

Physical Chemistry of Ionic Materials

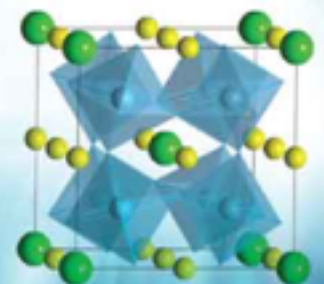
Ions and Electrons in Solids

JOACHIM MAIER

WILEY

SOLID STATE CHEMISTRY AND ITS APPLICATIONS

SECOND EDITION STUDENT EDITION

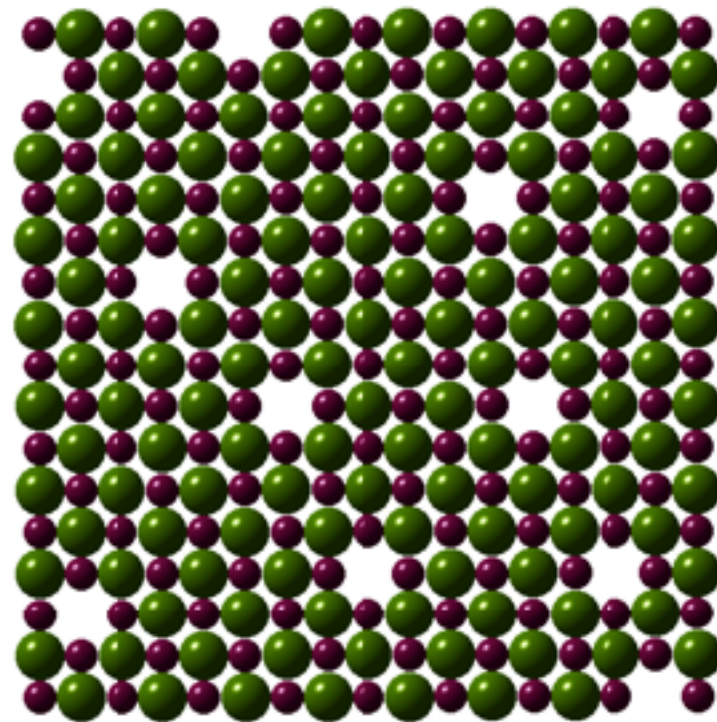
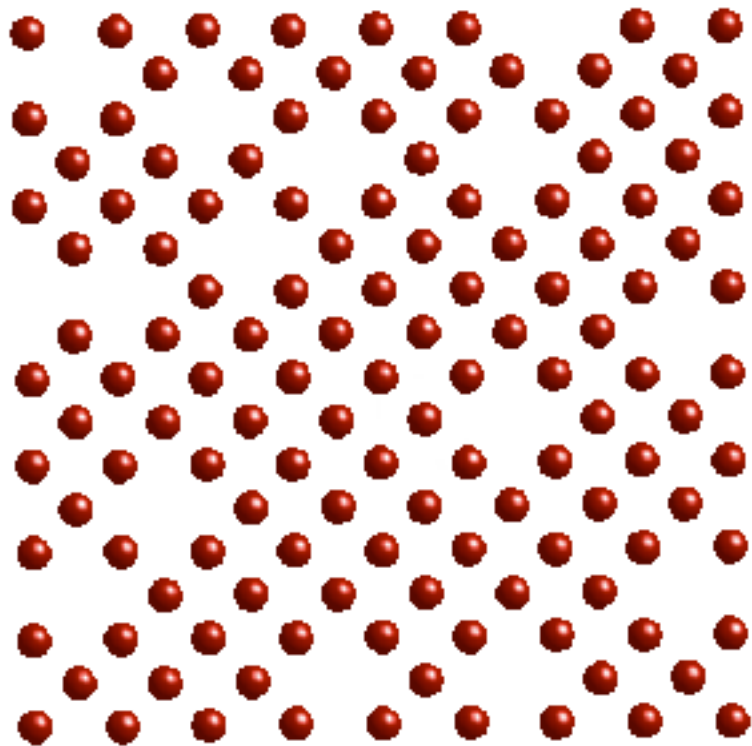


ANTHONY R. WEST

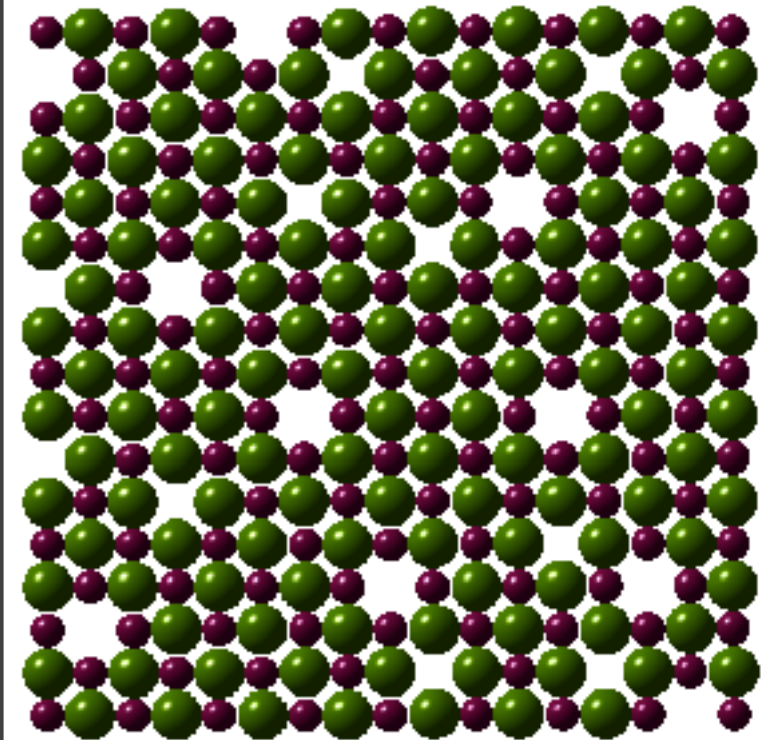
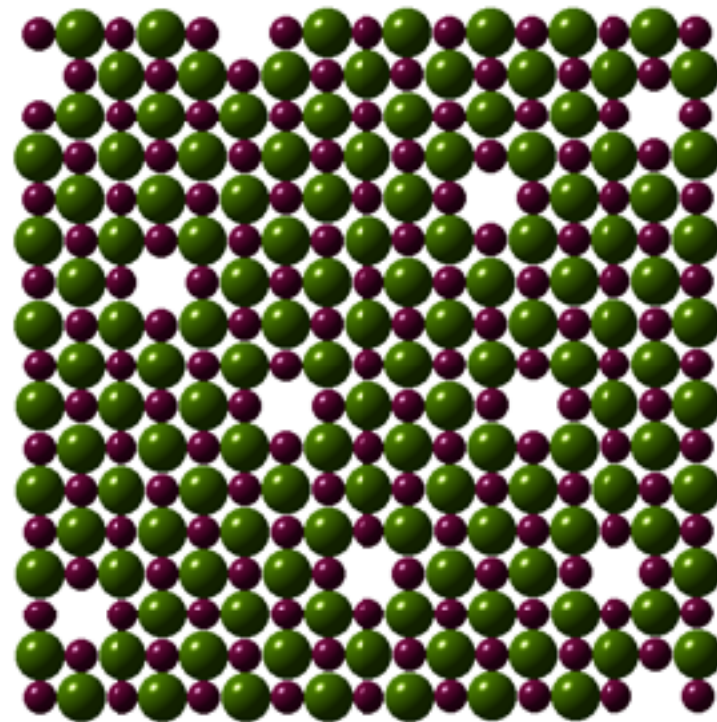
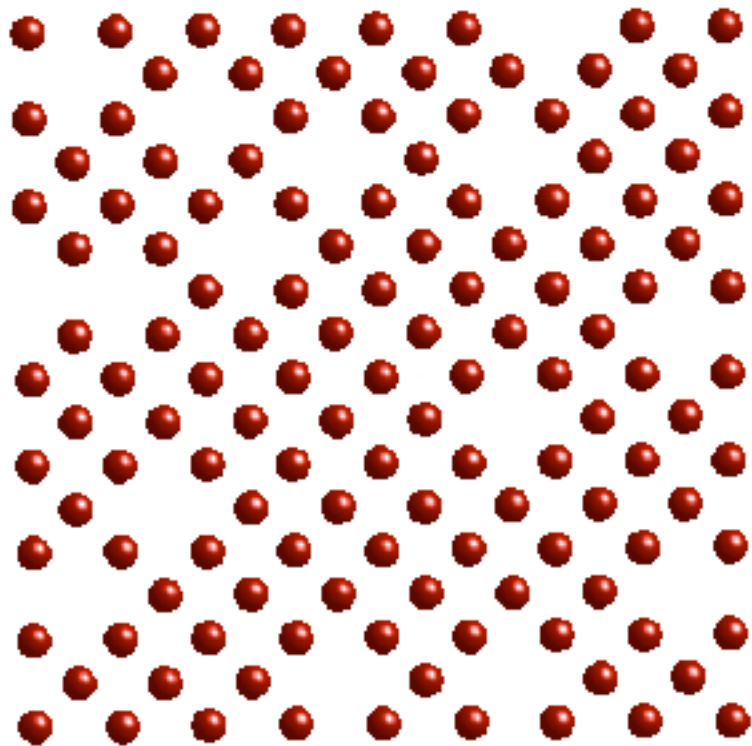
Section 2.2 and 2.3

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Metallic vs Ionic crystals

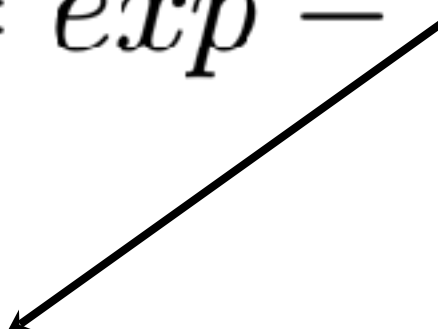


Metallic vs Ionic crystals

Defects in Ionic Crystals

Local Electroneutrality demands that:

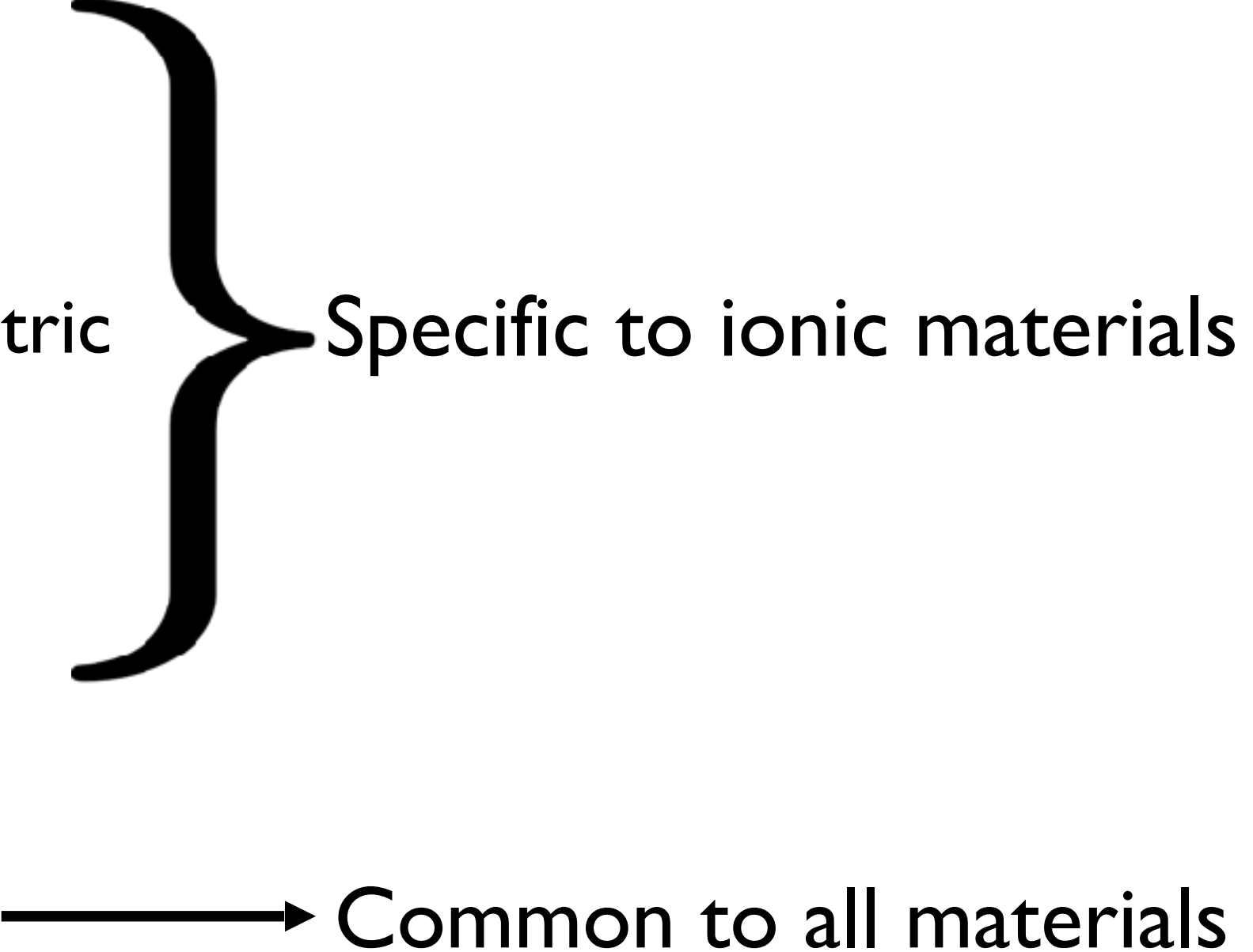
Nil \Rightarrow Positive Defect + Negative Defect

$$\left(\frac{n_{d+}}{n_+} \right) \times \left(\frac{n_{d-}}{n_-} \right) = \exp - \frac{\Delta G_m^*}{RT}$$


Composed of bonding and vibrational properties of the defect pair

Many other possibilities for defects exist

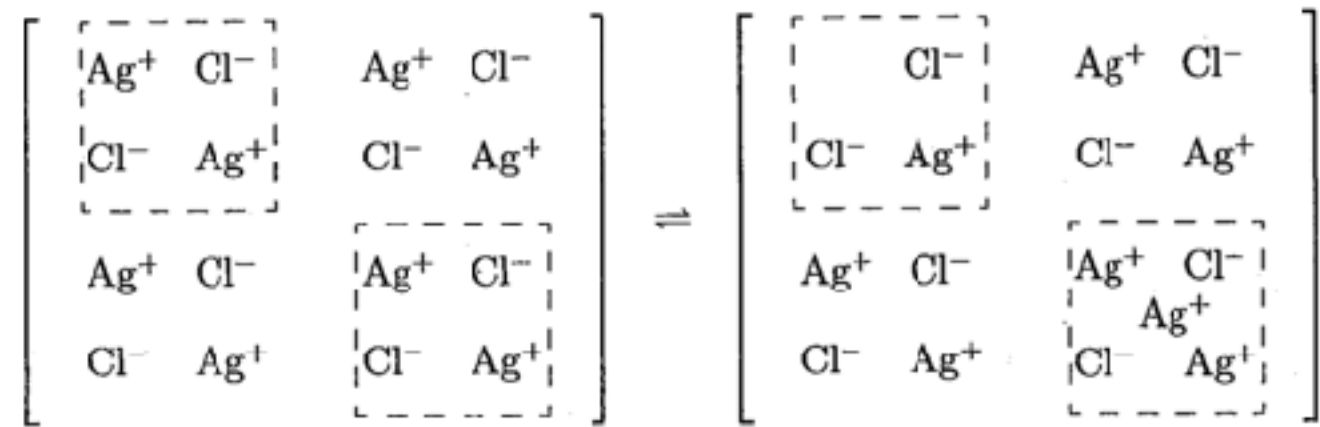
Types of Defects in Ionic Crystals

- Stoichiometric
 - Non-stoichiometric
 - Electronic
 - Extrinsic doping
- 
- Specific to ionic materials
- Common to all materials

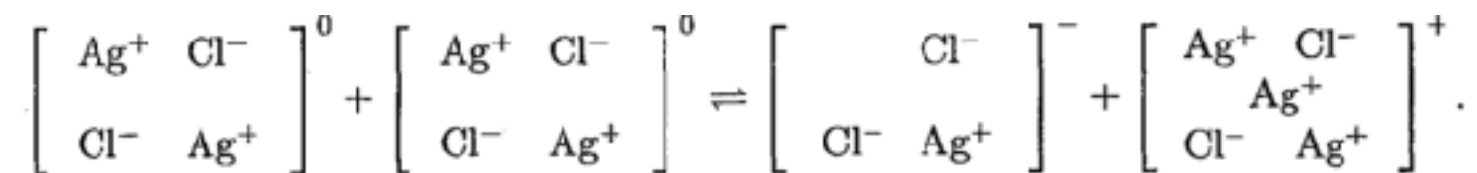
Stoichiometric defects

- Internal defect reactions
- Cation to anion ratio maintained in the crystal
 - Remove an ion from its' site and place it at a different site, but within the crystal lattice
 - Frenkel
 - Anion Frenkel
 - Remove/add cations and anions in pairs from their sites/ surfaces and place them in surface/interstitial positions
 - Schottky
 - Anti-Schottky

Frenkel Defect Pair Formation



Considering only the sections that have changed



Notation for defects - Kröger-Vink

General Format : M_s^c

- M corresponds to the structural element
 - Atoms
 - Vacancies
 - electrons/holes
- S - Lattice site that the structural element occupies
 - Regular site
 - Interstice
- C - Charge of the defect relative to site that it occupies

Kröger-Vink notation - AgCl

$V'_{\text{Ag}} \Rightarrow$ Vacancy on a silver site

$V_{\text{Cl}}^{\bullet} \Rightarrow$ Vacancy on a chlorine site

$\text{Ag}_i^{\bullet} \Rightarrow$ Silver Interstitial

$\text{Cl}'_i \Rightarrow$ Chlorine interstitial

The Frenkel defect reaction becomes: $\text{Ag}_{\text{Ag}}^{\text{x}} + V_i^{\text{x}} \rightleftharpoons \text{Ag}_i^{\bullet} + V'_{\text{Ag}}$

Mass Action Law - Frenkel defect

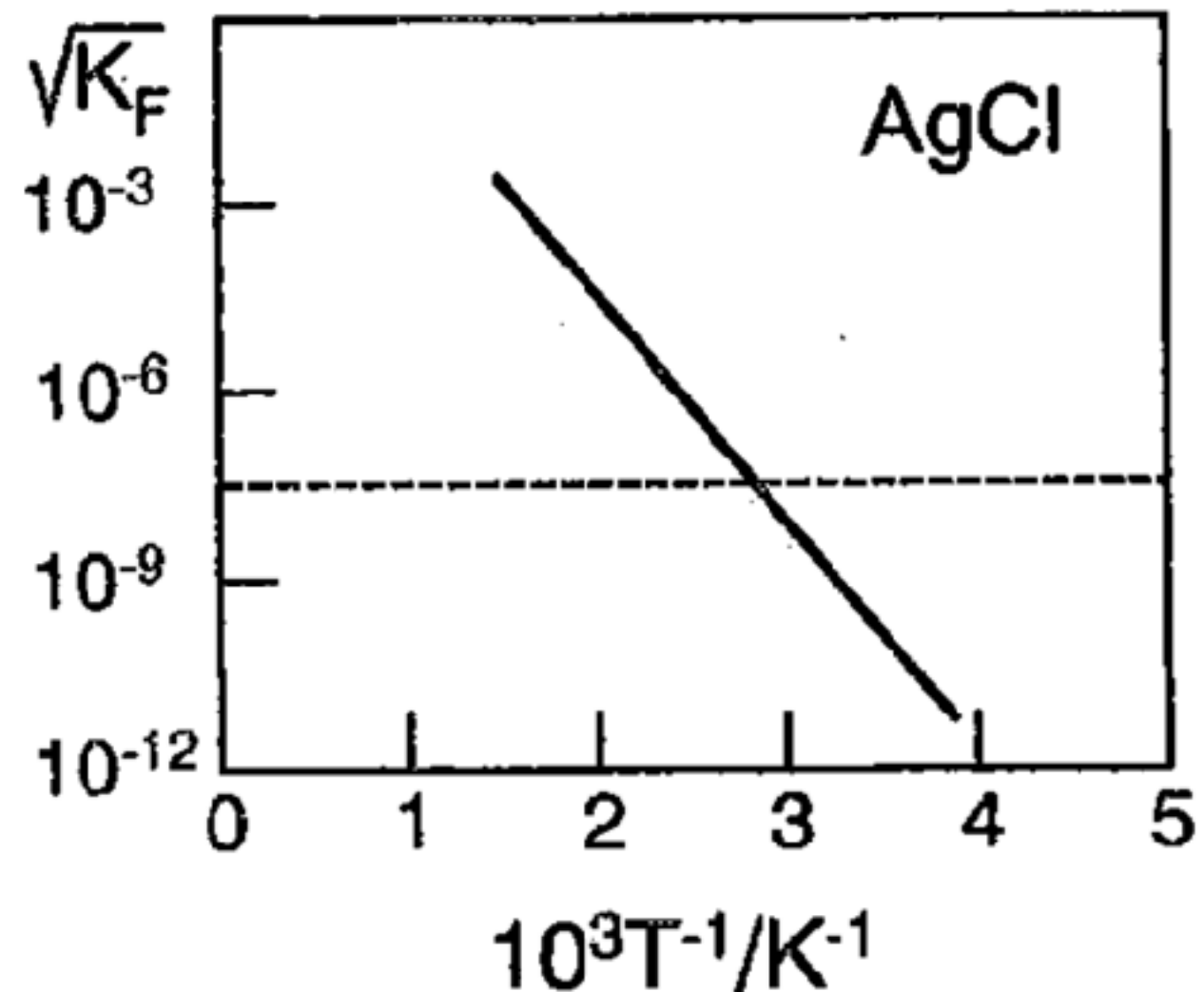
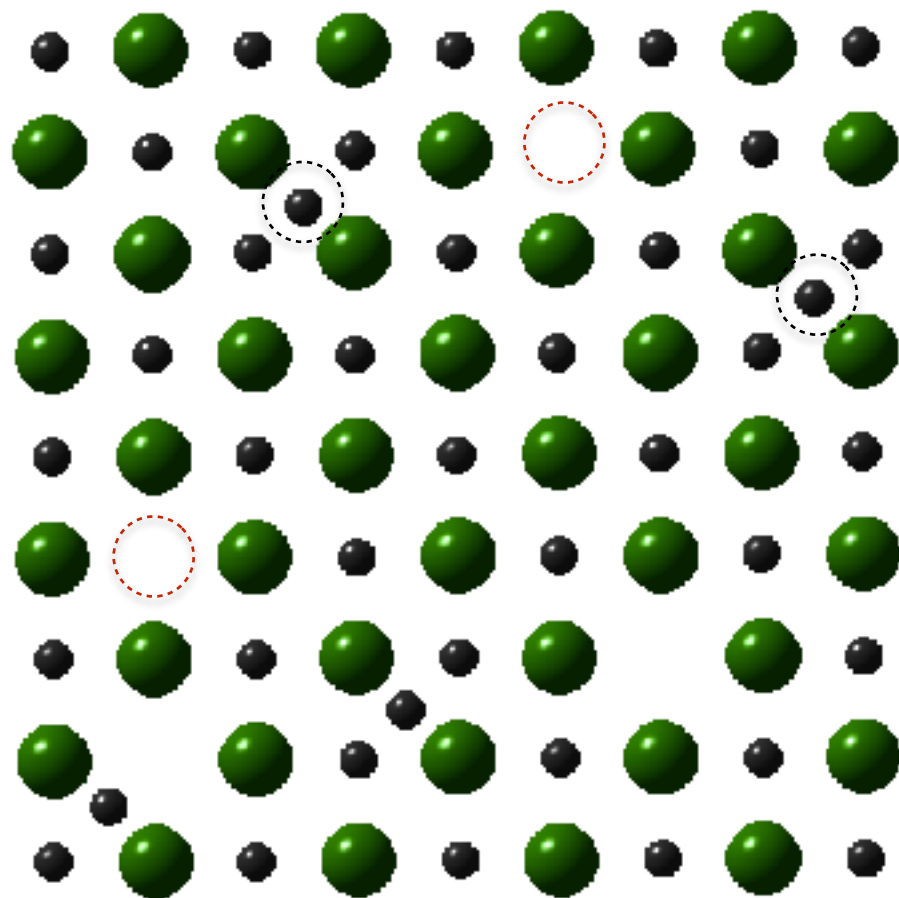
where $K_F = \exp\left(-\frac{\Delta_F G^0}{RT}\right)$

$$[Ag_i^\bullet] [V'_{Ag}] = \alpha N^2 \times K_F$$

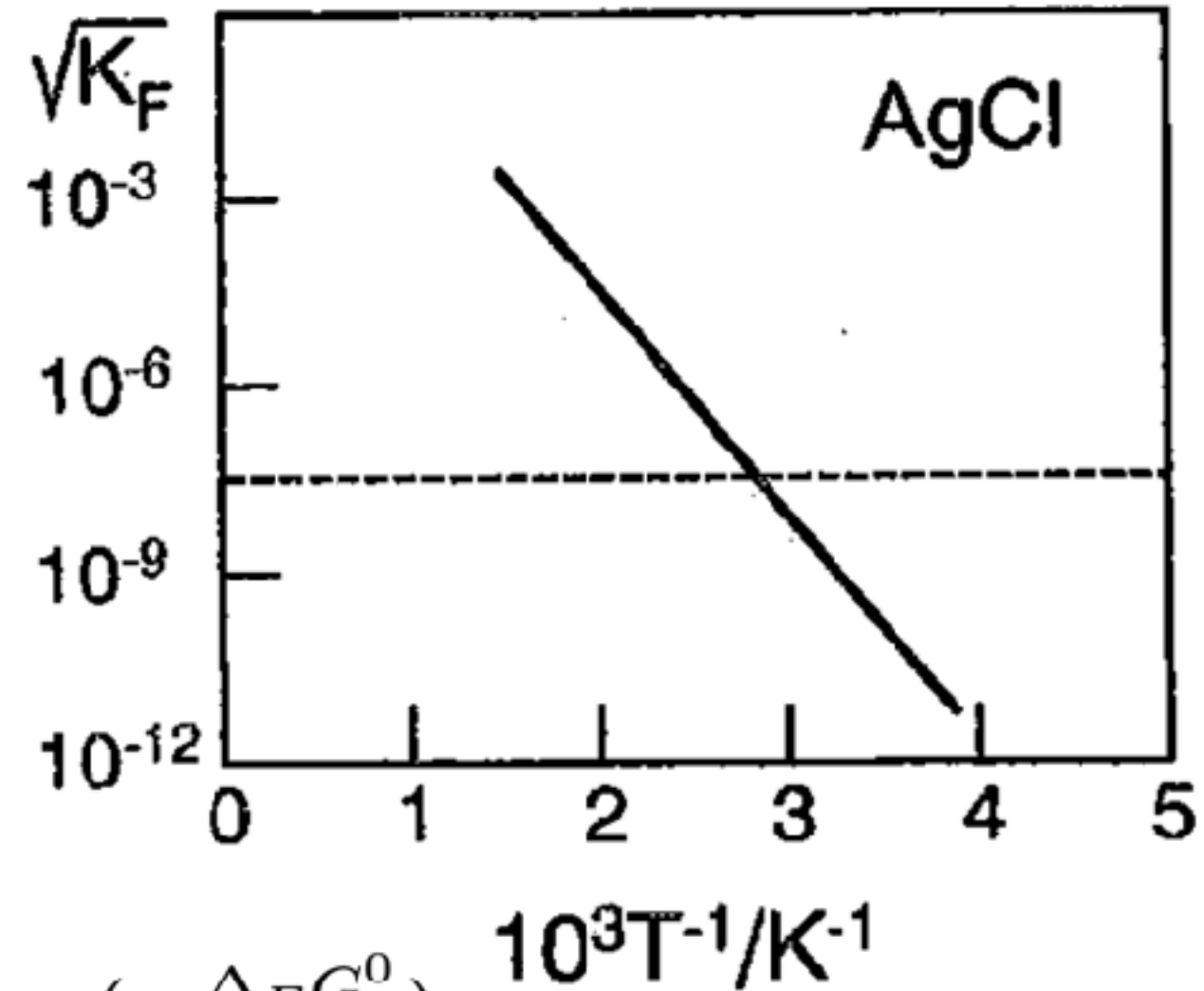
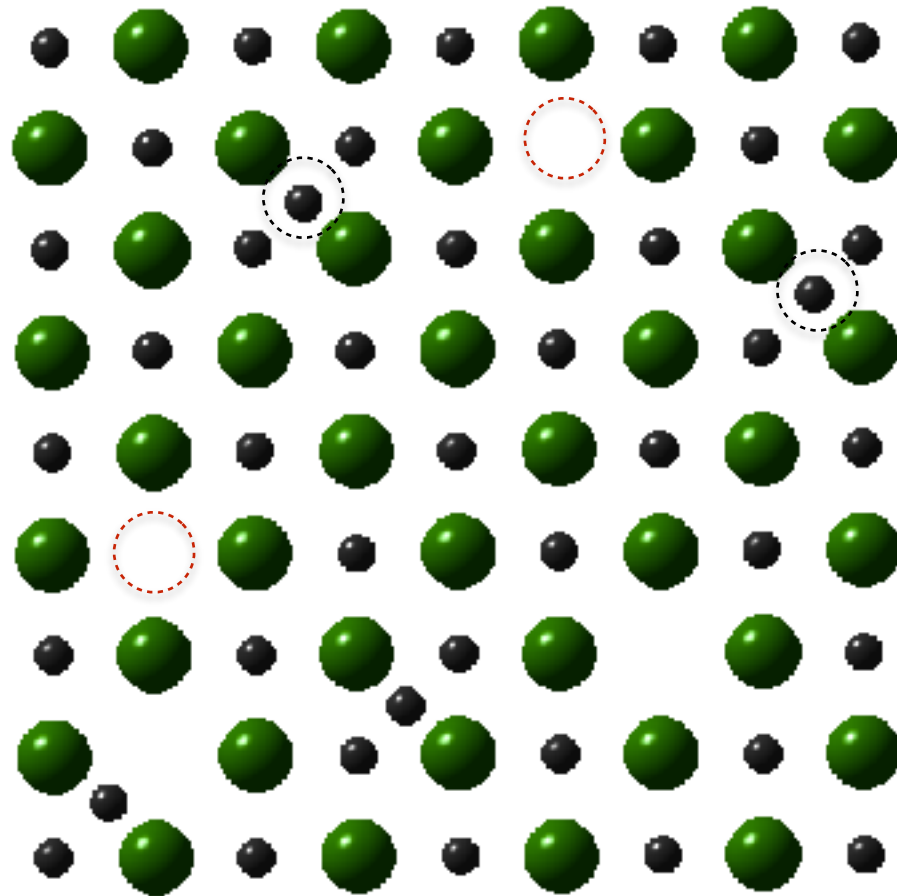
$N \rightarrow$ No. of atomic sites/cc

$\alpha \rightarrow$ Interstitial/atomic

electroneutrality: $[Ag_i^\bullet] = [V'_{Ag}] = \sqrt{K_F(T)} \times N\sqrt{\alpha}$

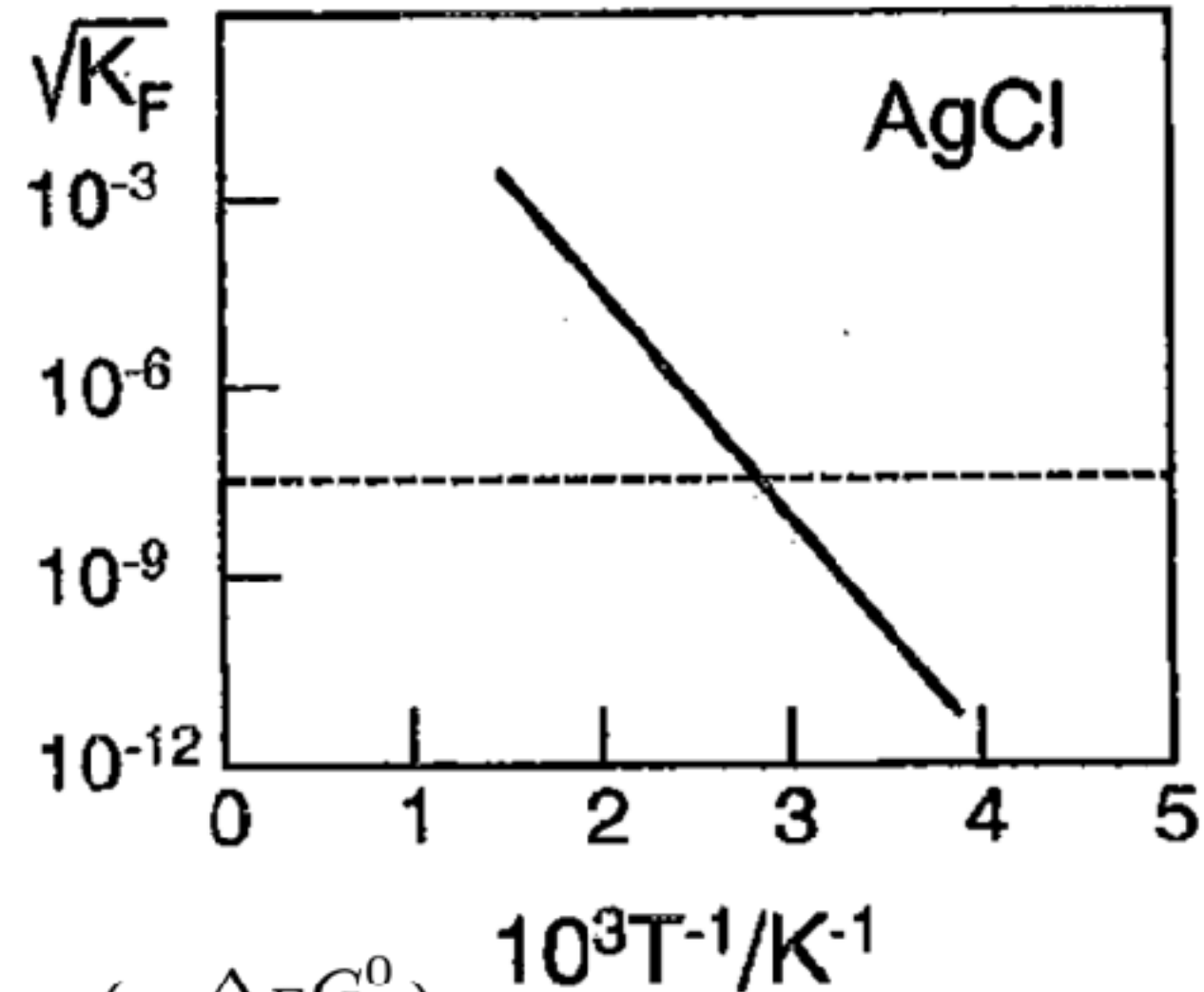
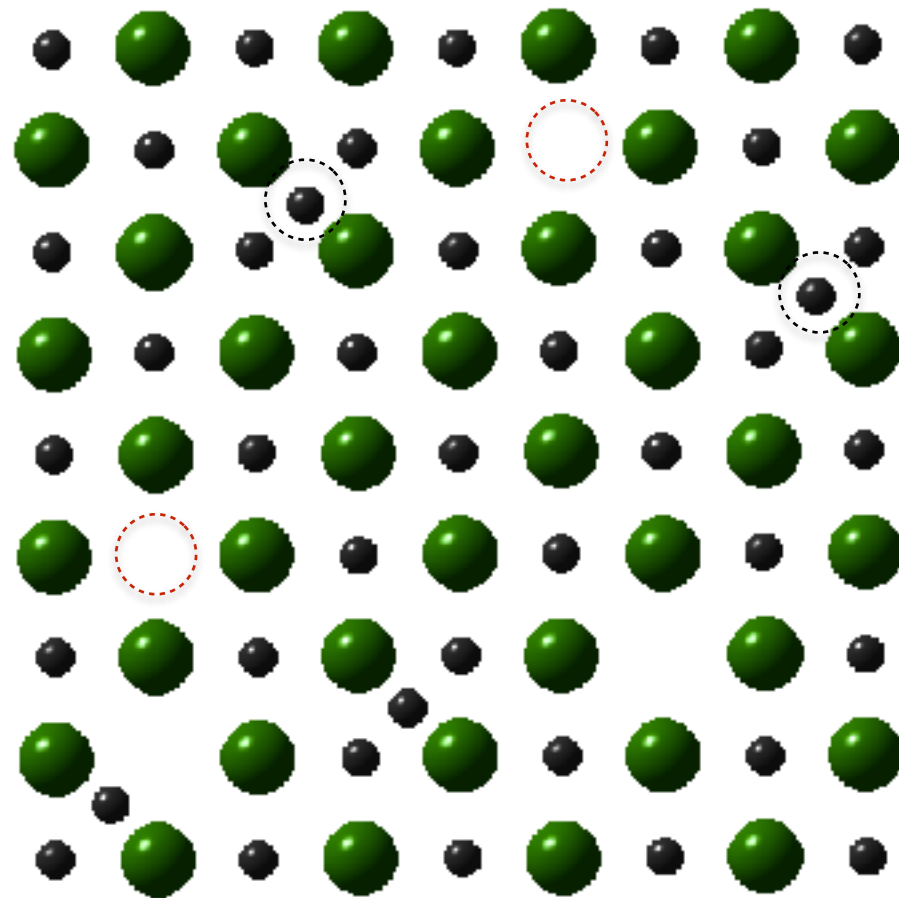


Energetics - Frenkel defect



where $K_F = \exp\left(-\frac{\Delta_F G^0}{RT}\right)$

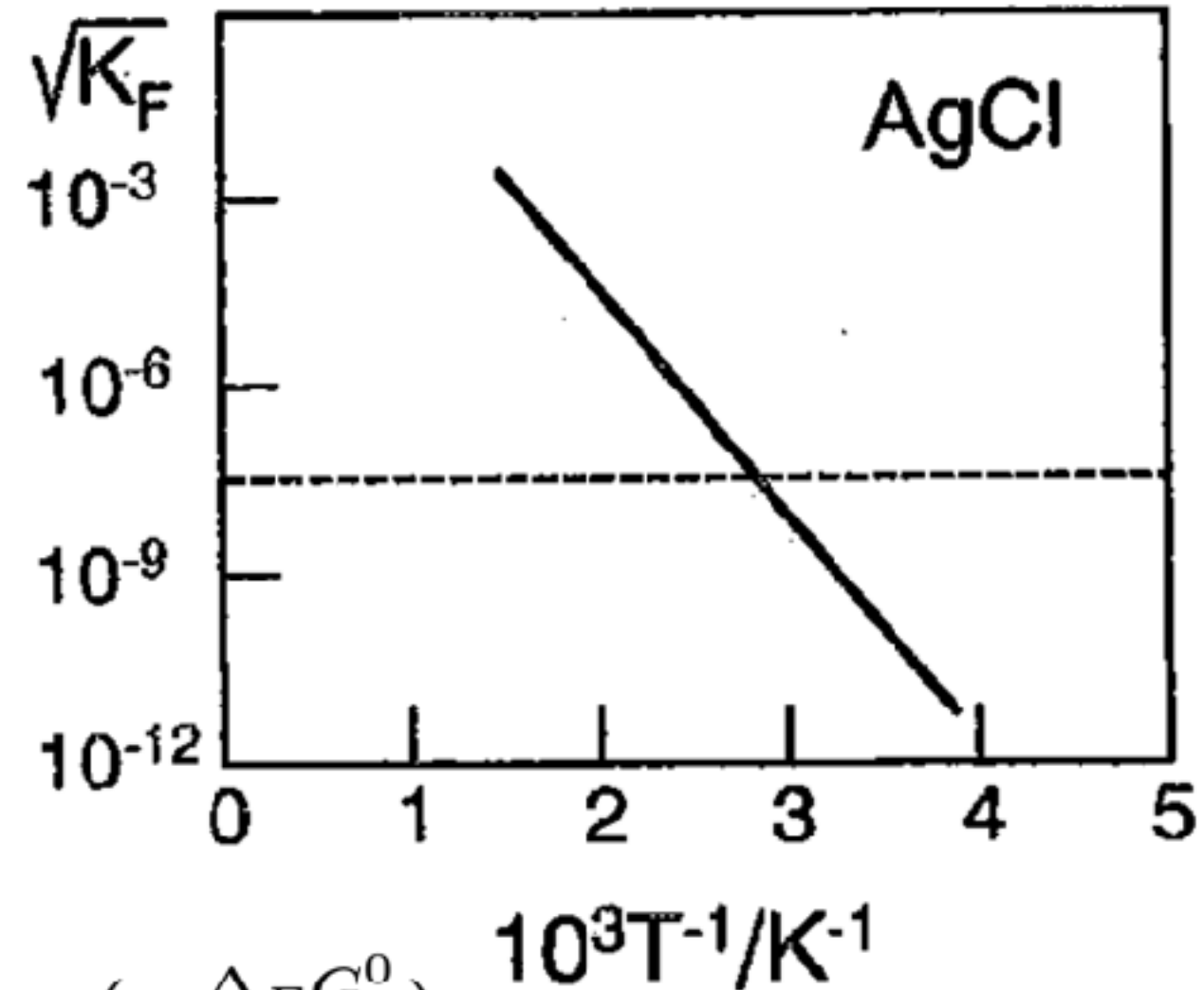
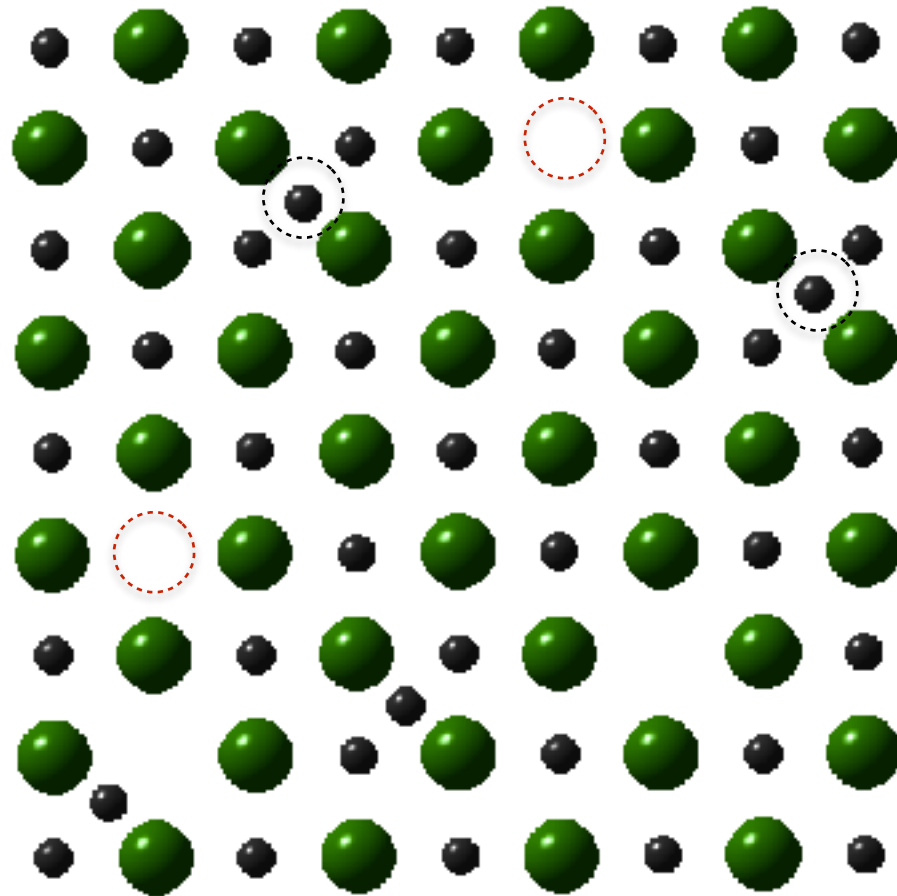
Energetics - Frenkel defect



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$$\Rightarrow [Ag_i^\bullet] = [V'_{Ag}] = N\sqrt{\alpha \times K_F} = \exp\left(\frac{\Delta S_F^0}{2R}\right) \exp\left(-\frac{\Delta H_F^0}{2RT}\right)$$

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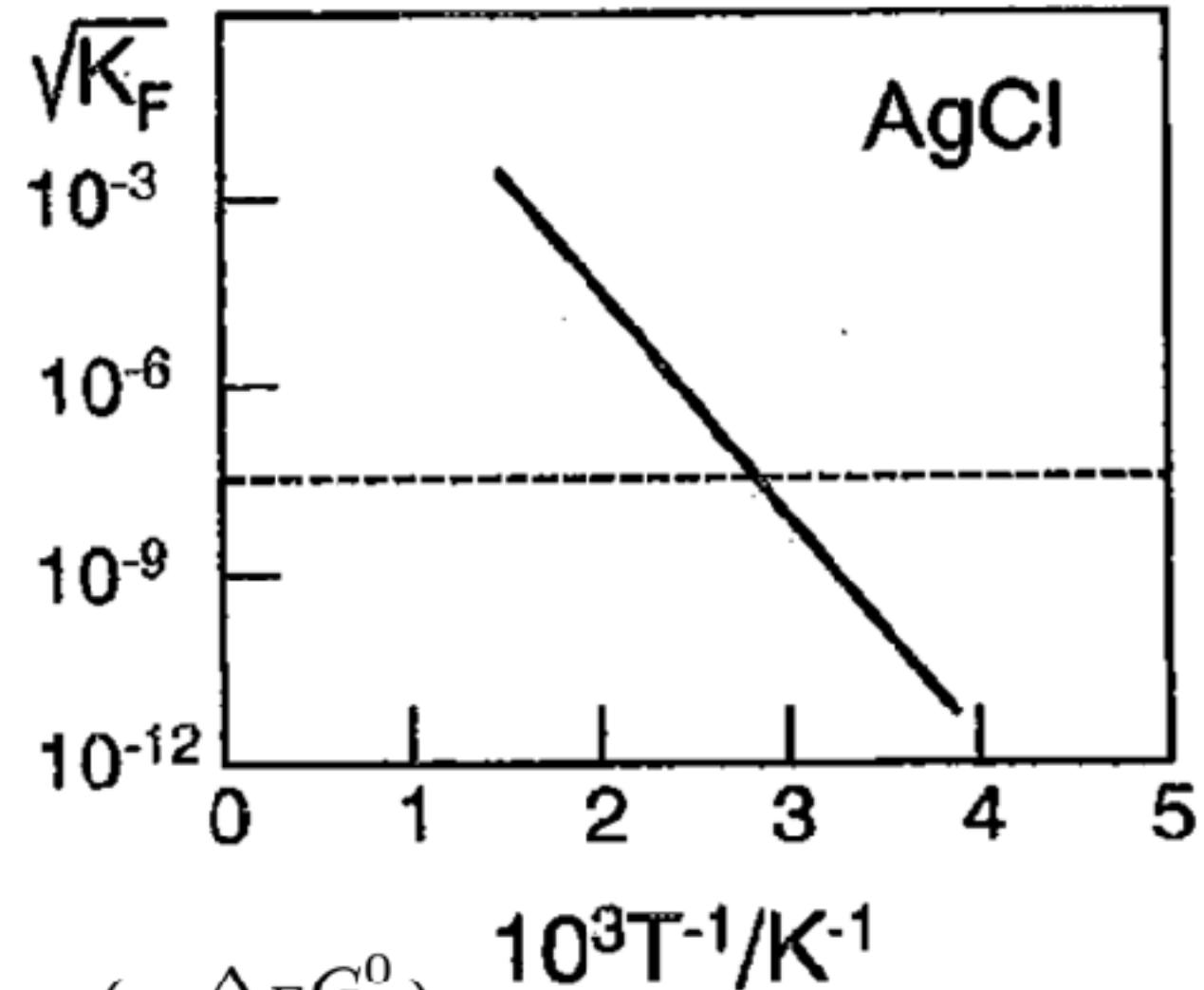
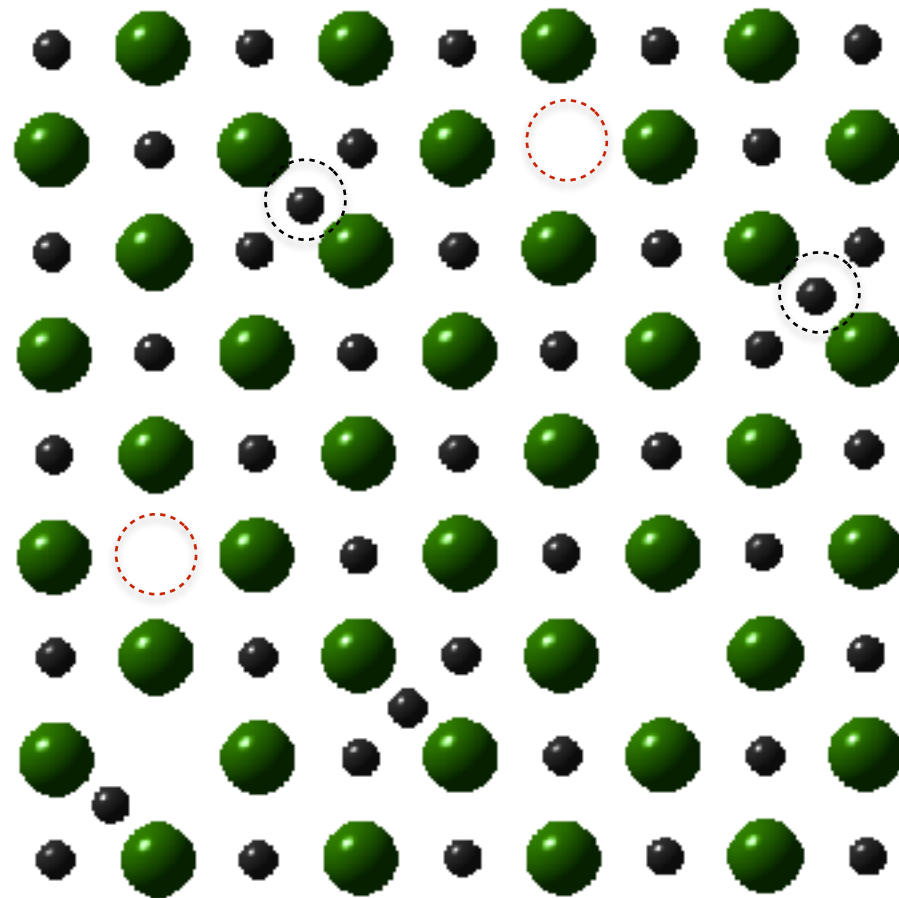


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$$\Delta S_F^0 \approx 9.4R$$

Energetics - Frenkel defect



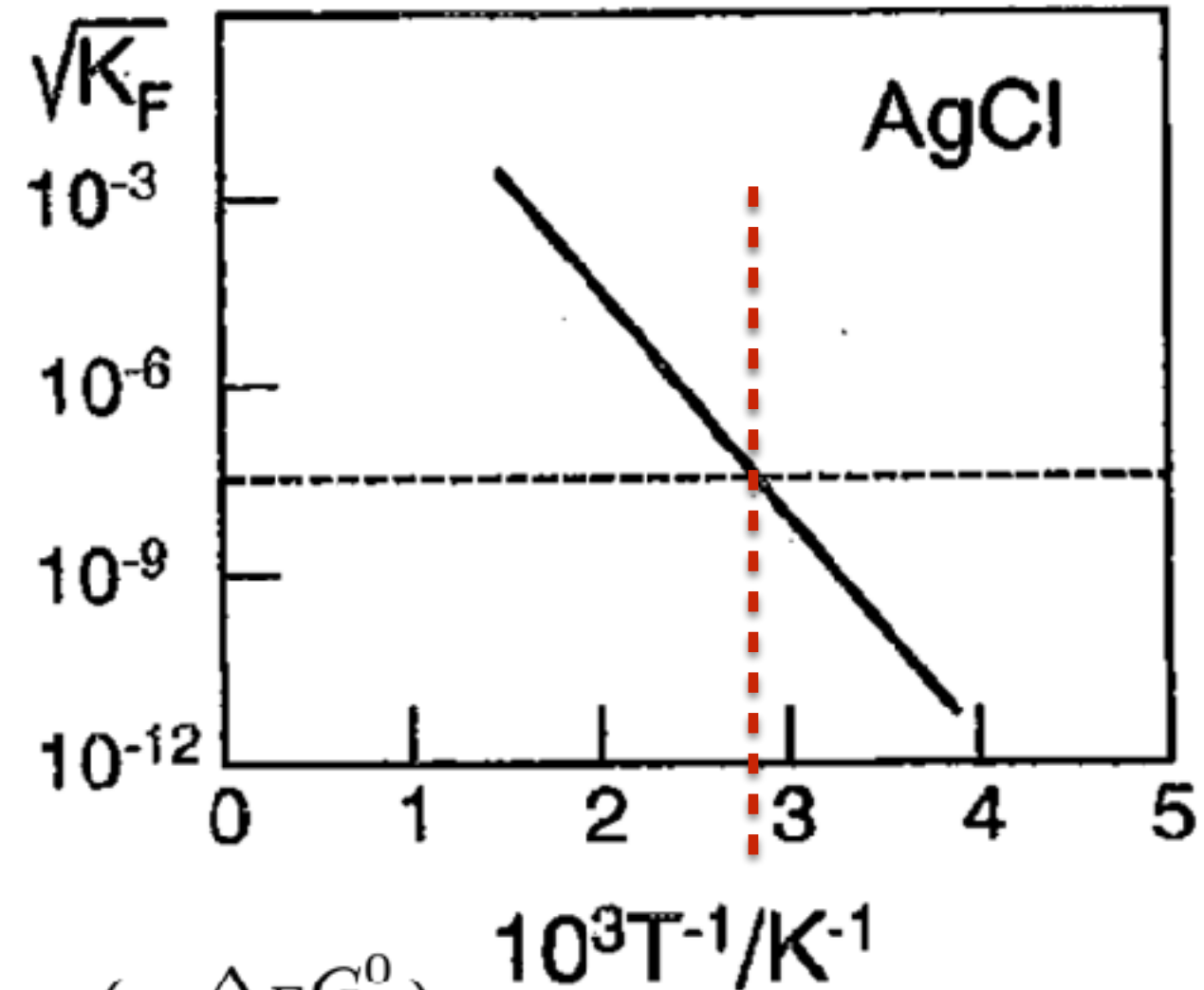
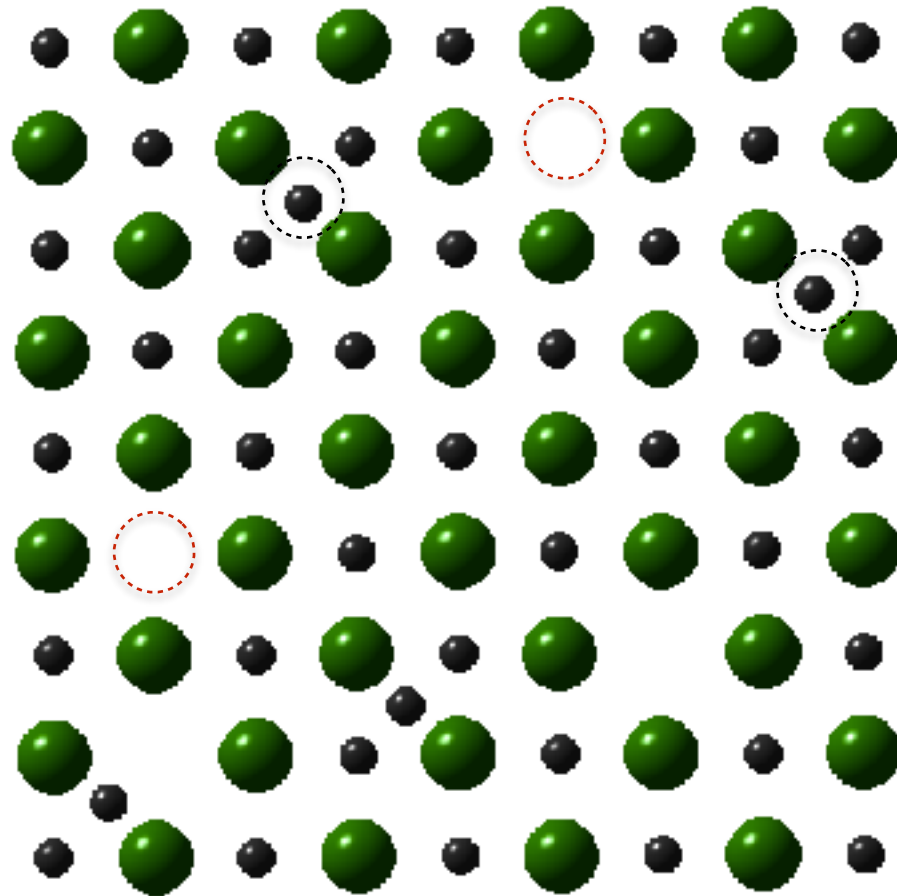
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$$\Delta H_F^0 \approx 140 \text{ kJ.mol}^{-1}$$

Energetics - Frenkel defect



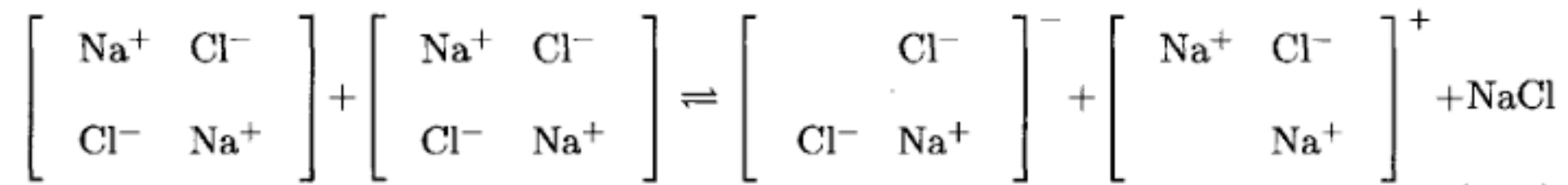
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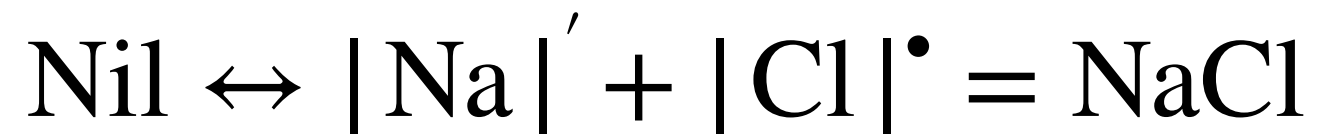
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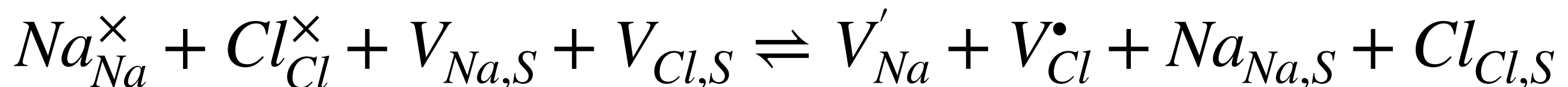
Schottky defect - NaCl



Building Element Notation :



Kroger-Vink Notation :

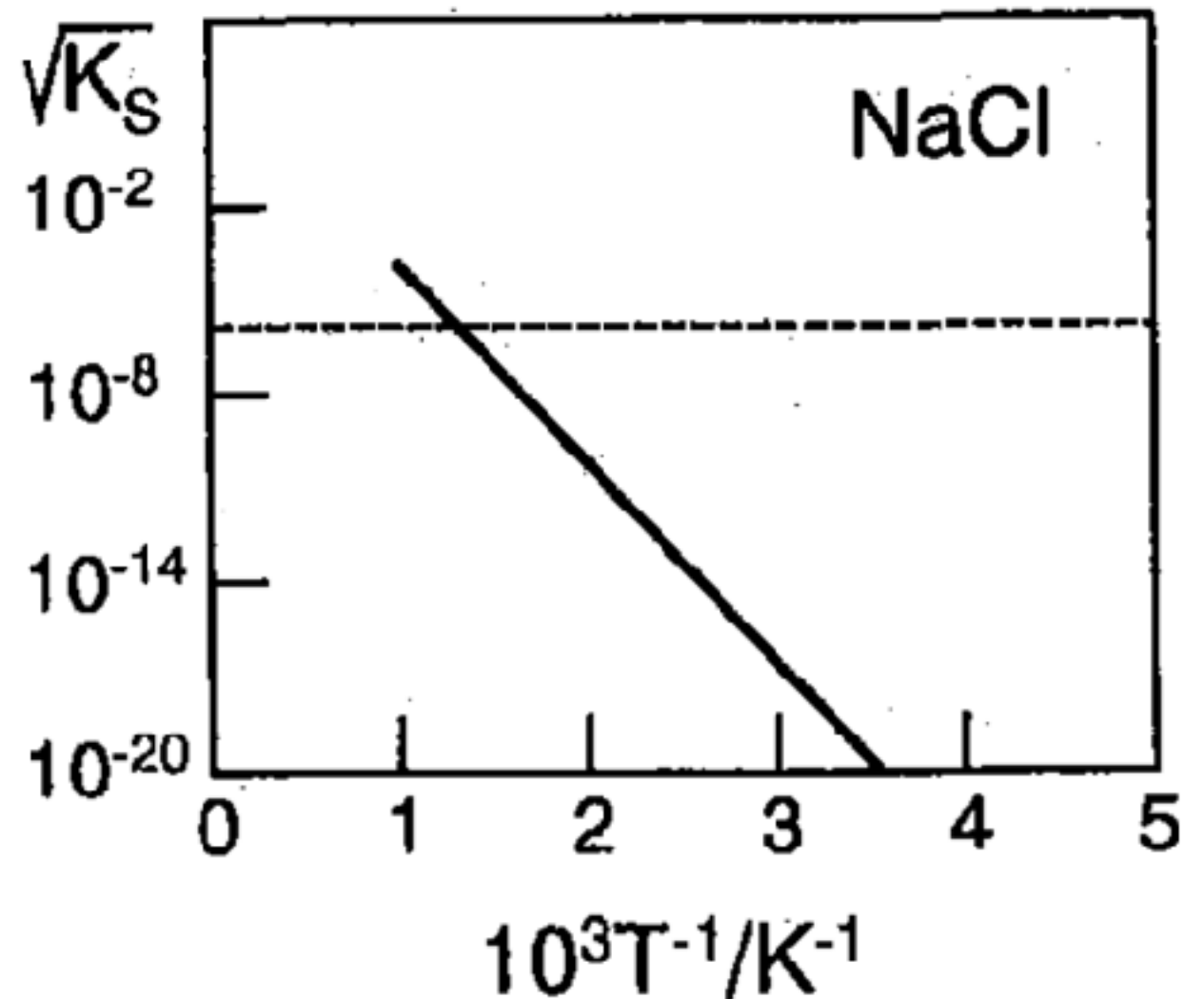
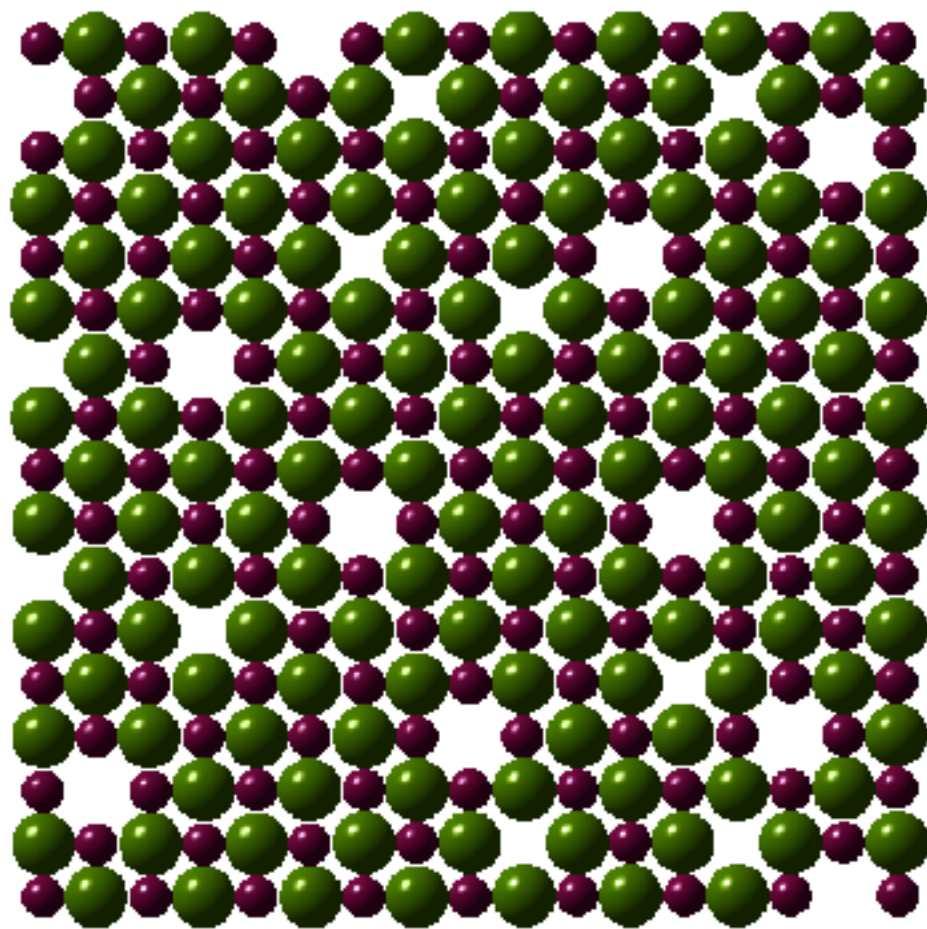


Mass Action Law - Schottky defect

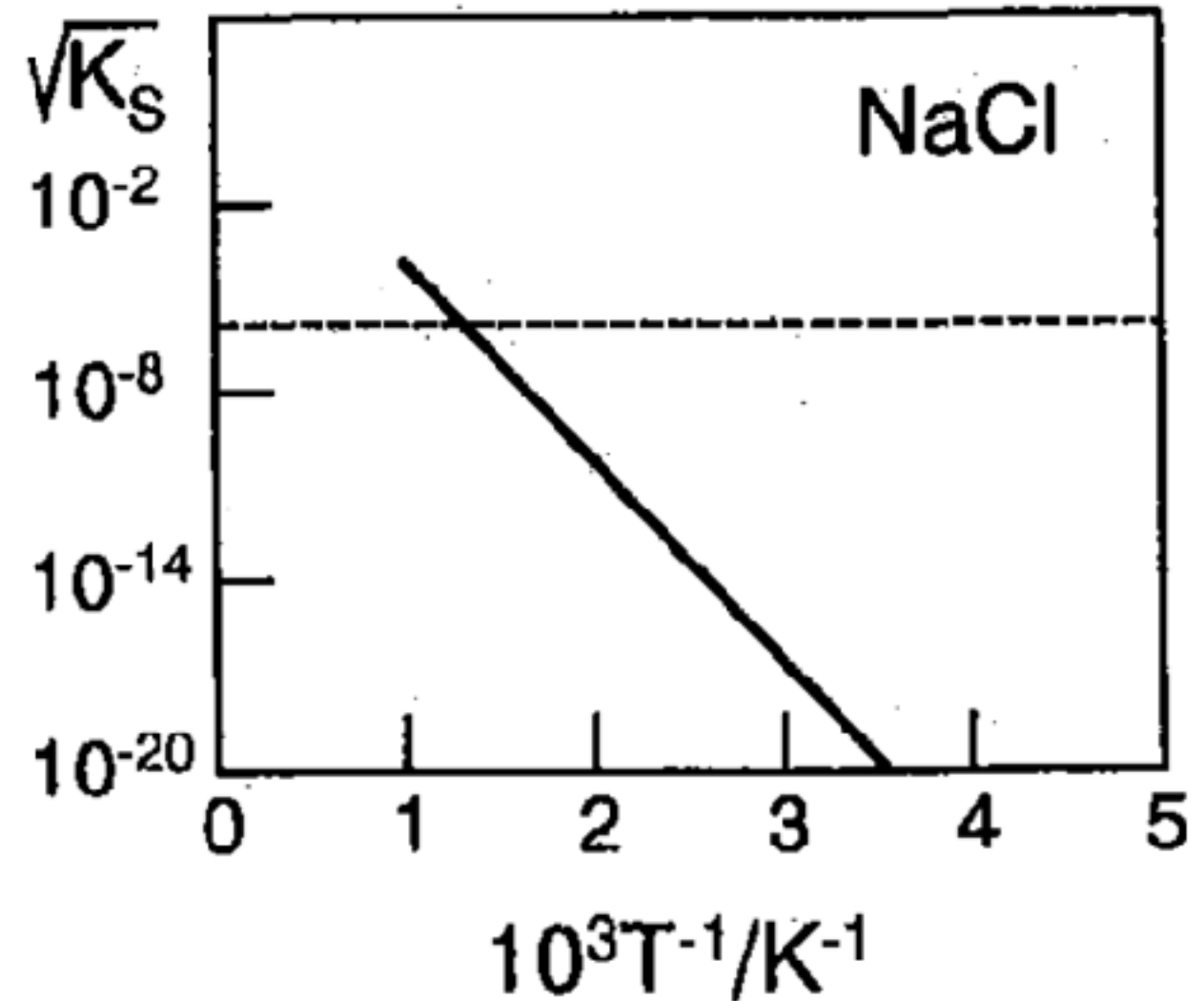
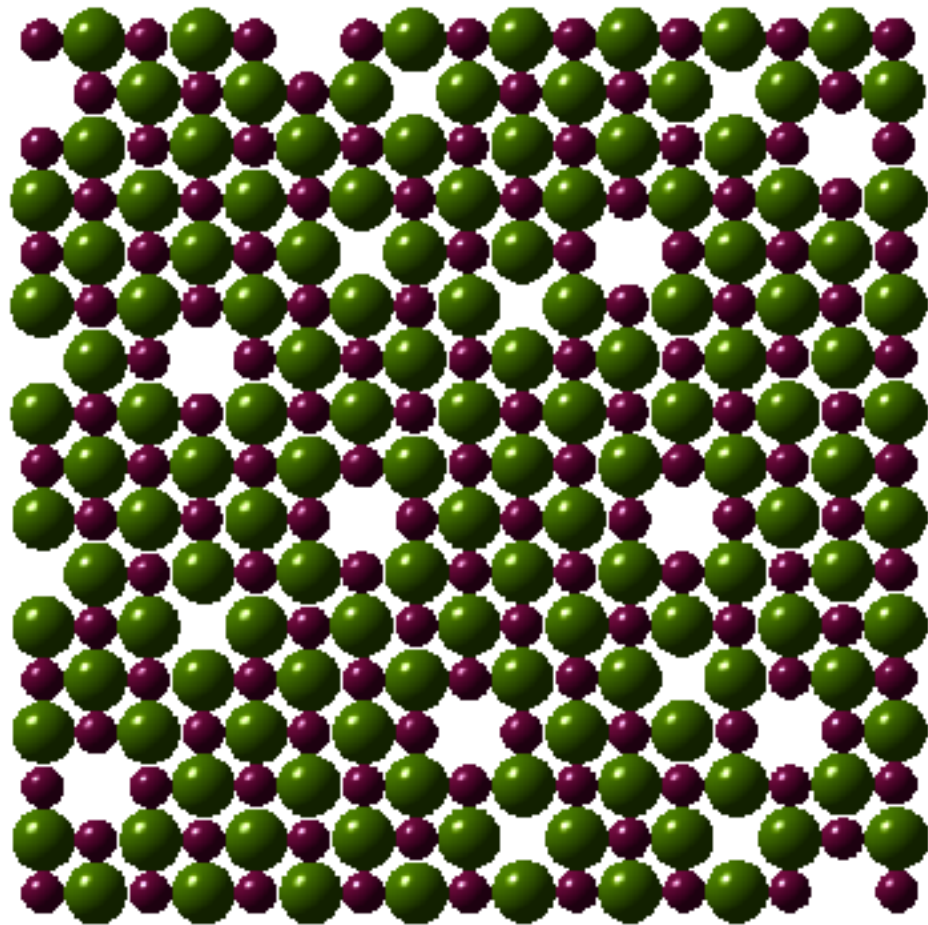
Schottky reaction:



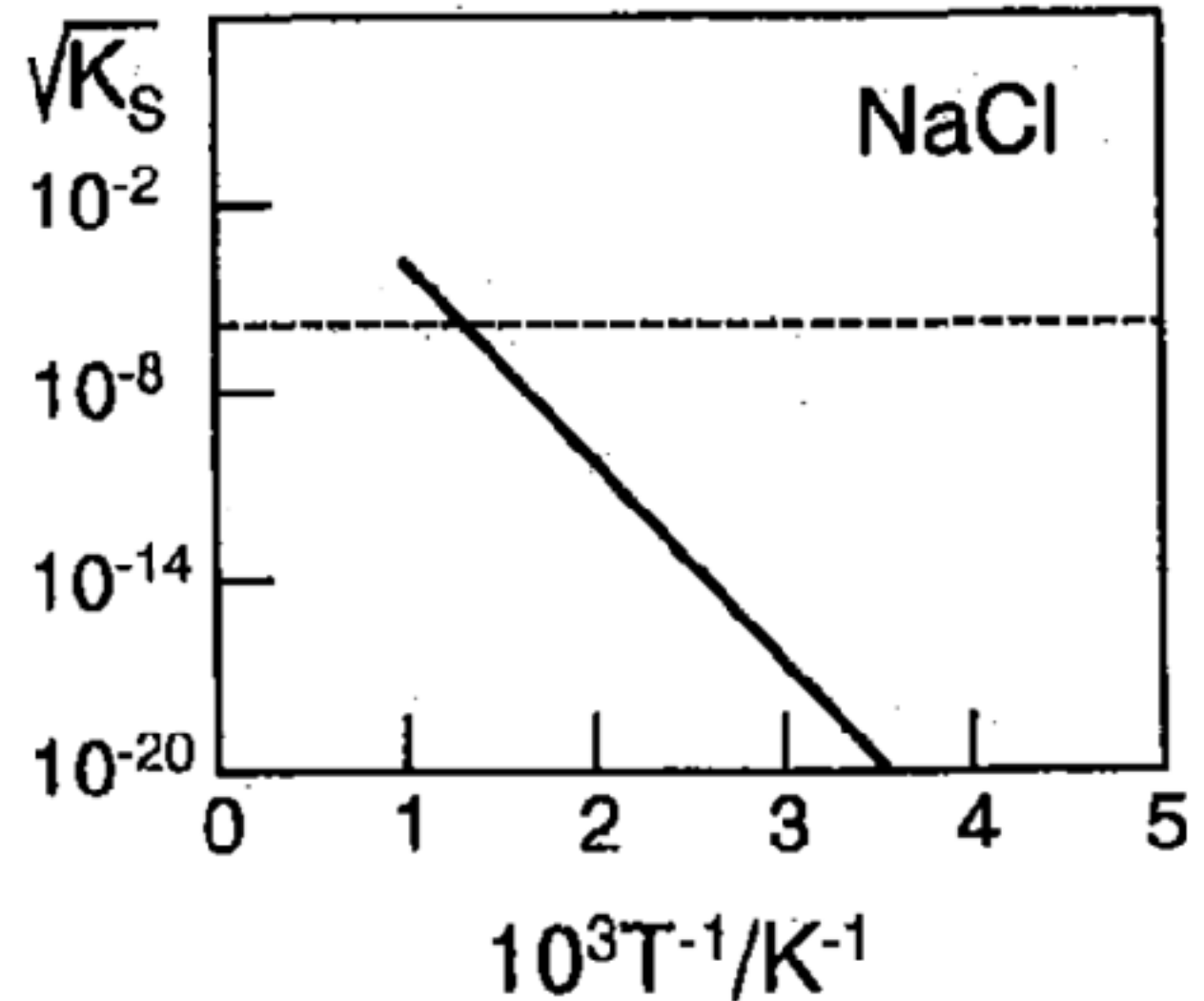
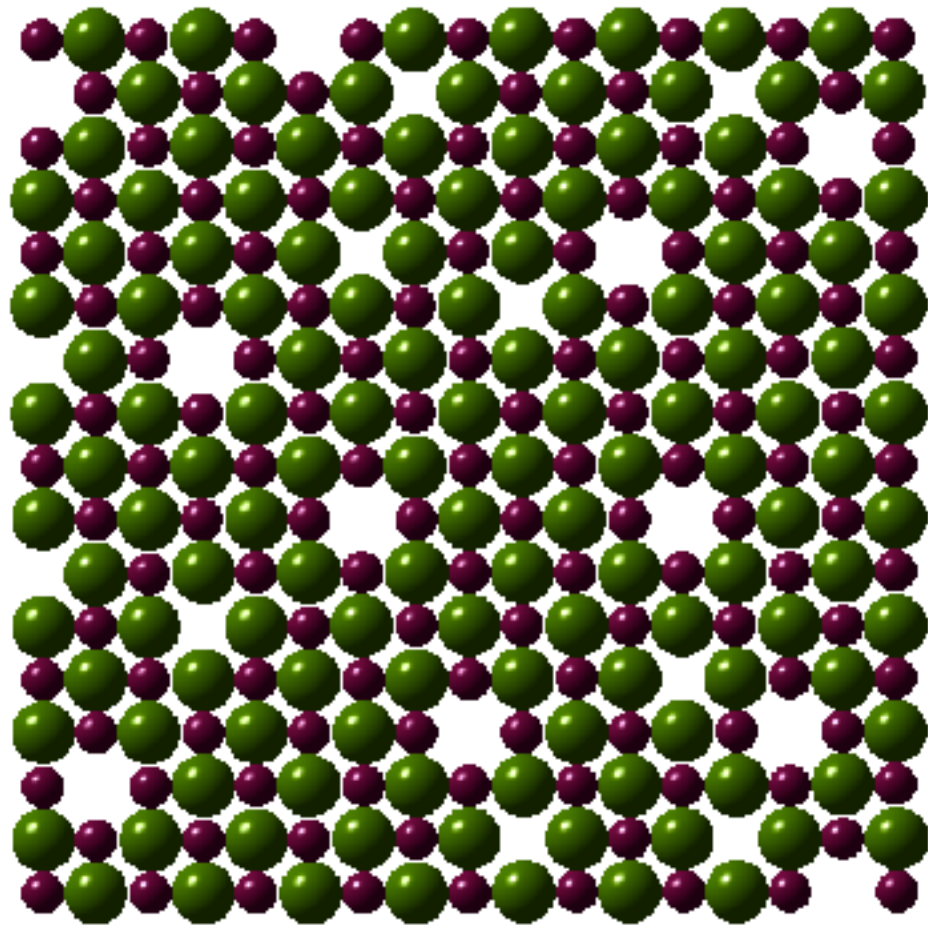
electroneutrality: $[V^{\bullet}_{Cl}] = [V'_{Na}] = \sqrt{K_s(T)} \times N$



Energetics - Schottky defect

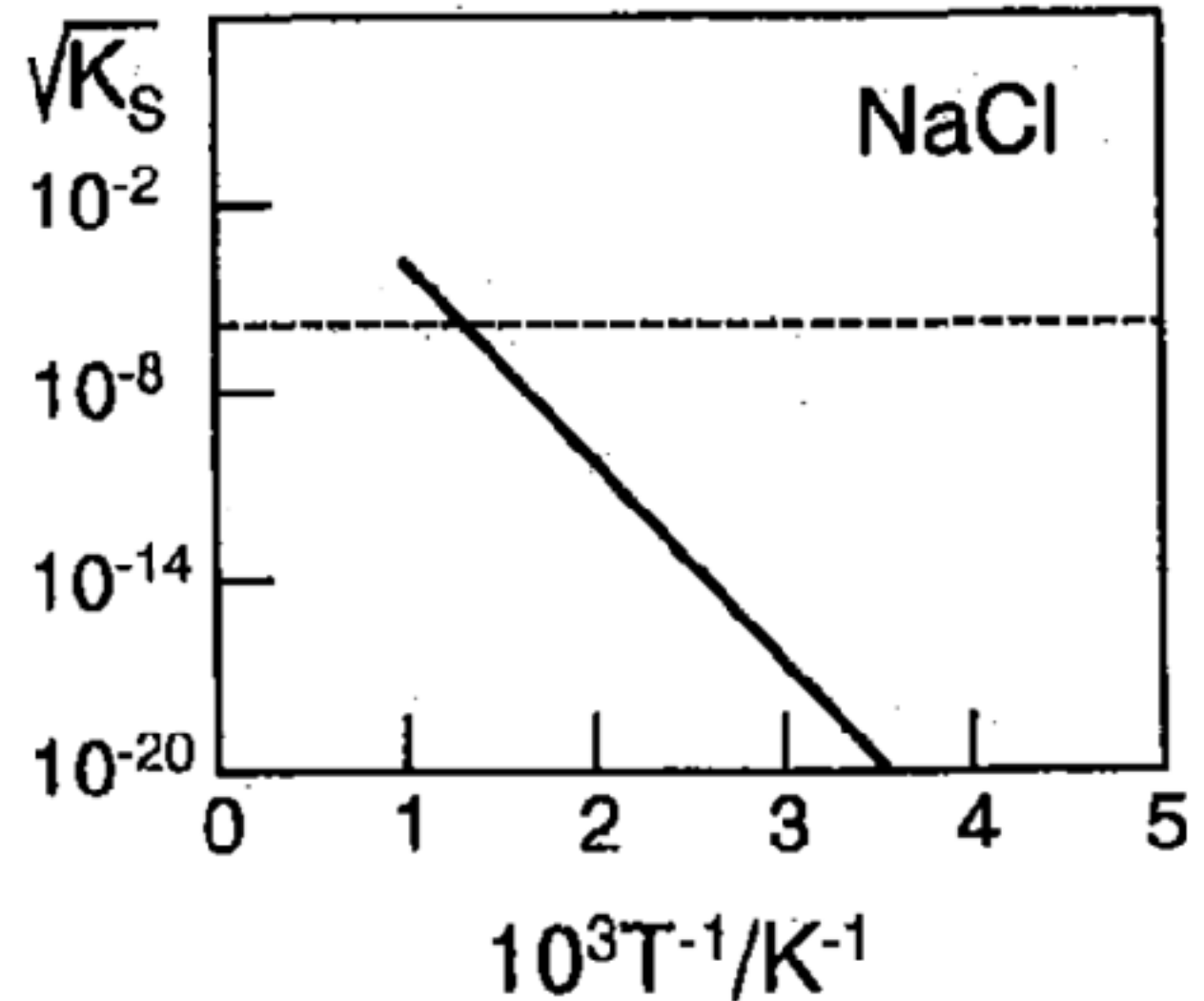
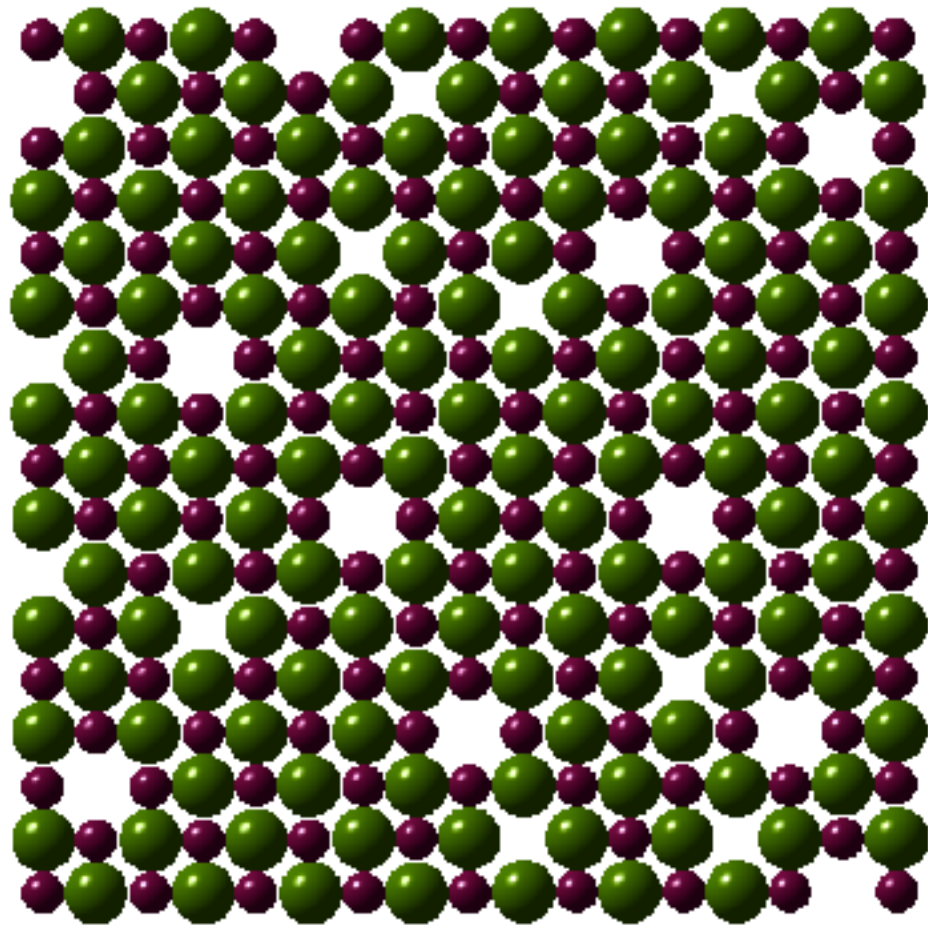


Energetics - Schottky defect



$$\Rightarrow [V_{Cl}^{\bullet}] = [V'_{Na}] = N\sqrt{K_S} = \exp\left(\frac{\Delta S_S^0}{2R}\right) \exp\left(-\frac{\Delta H_S^0}{2RT}\right)$$

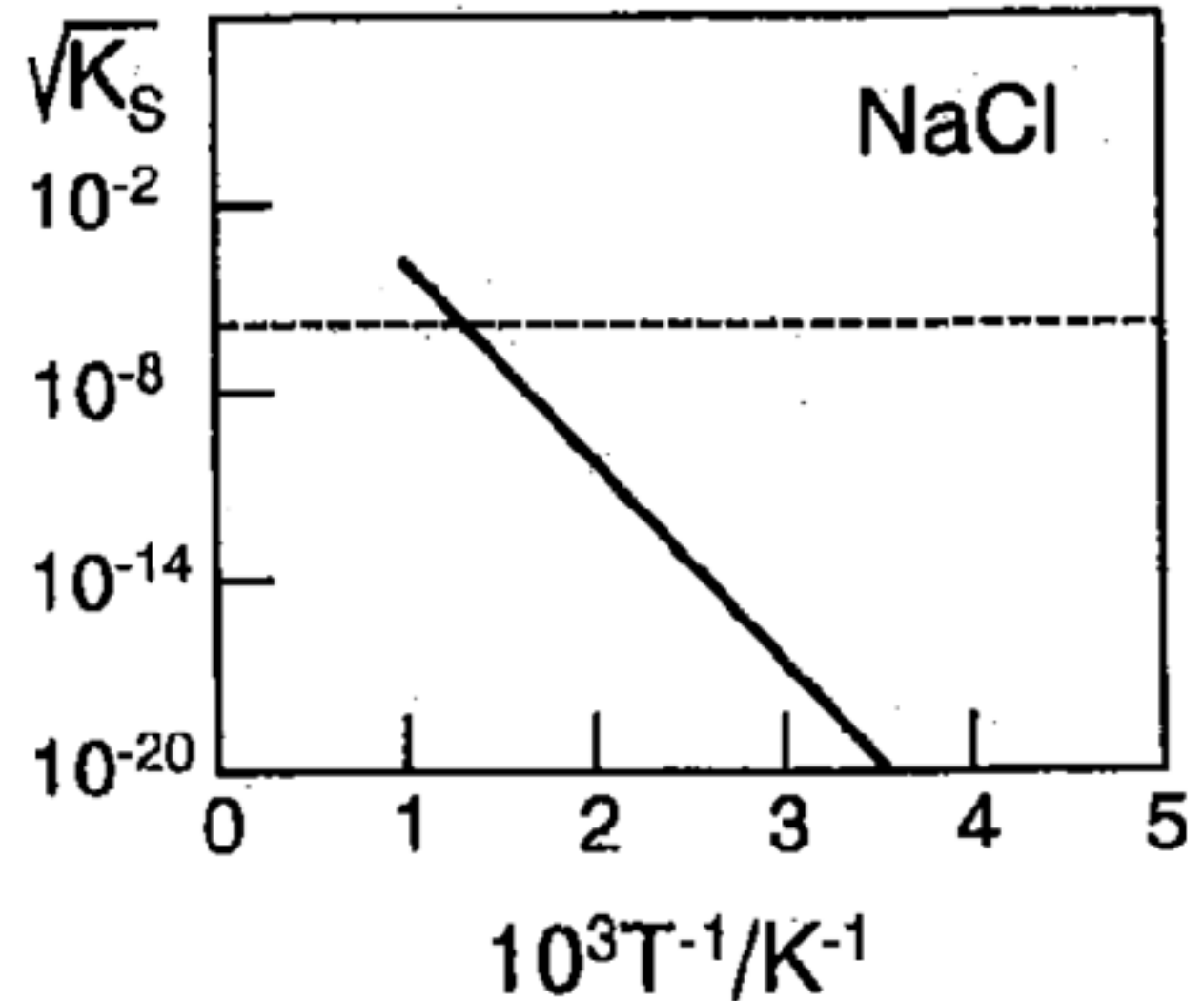
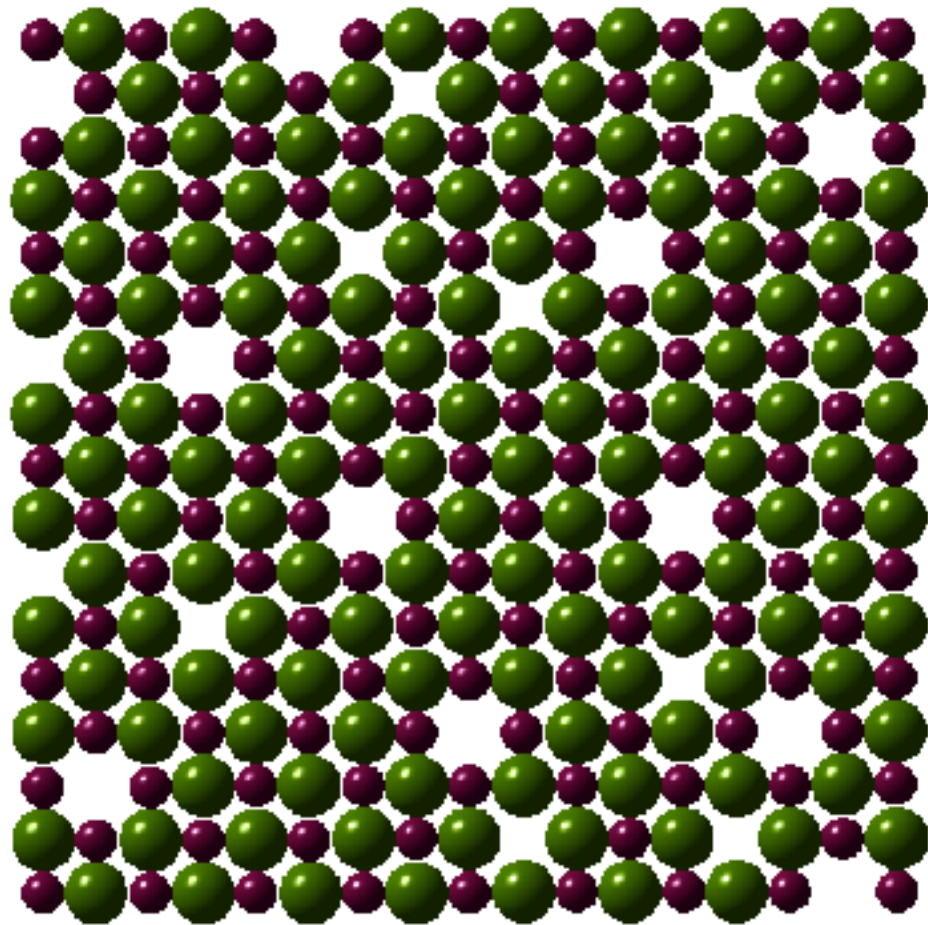
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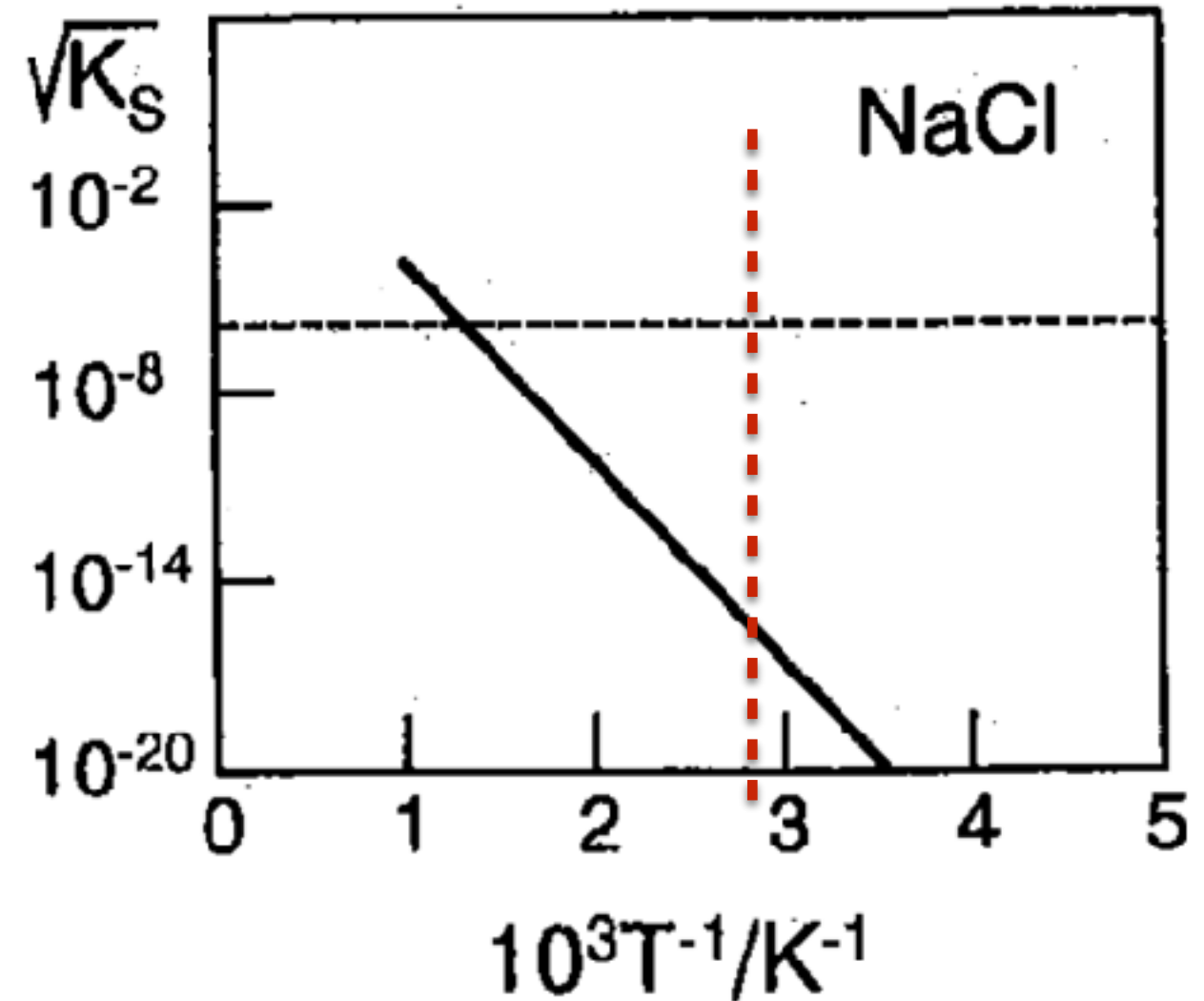
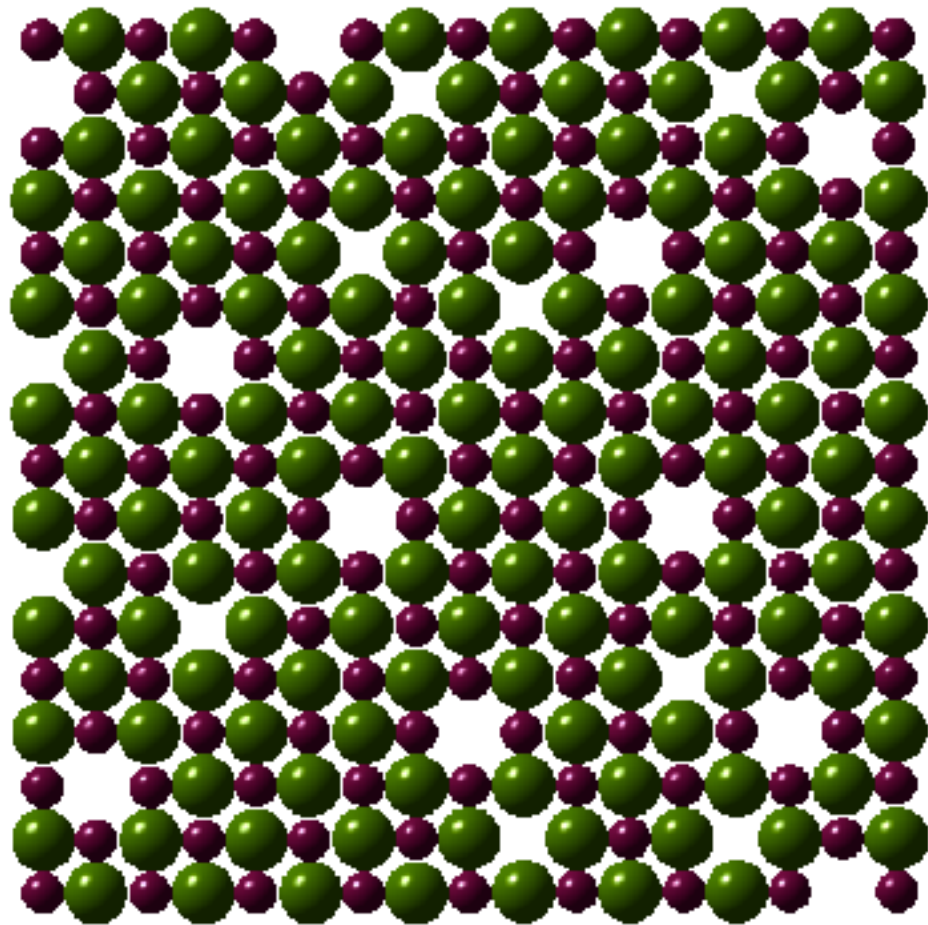


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$$\Delta H_S^0 \approx 240 \text{ kJ.mol}^{-1}$$

Energetics - Schottky defect

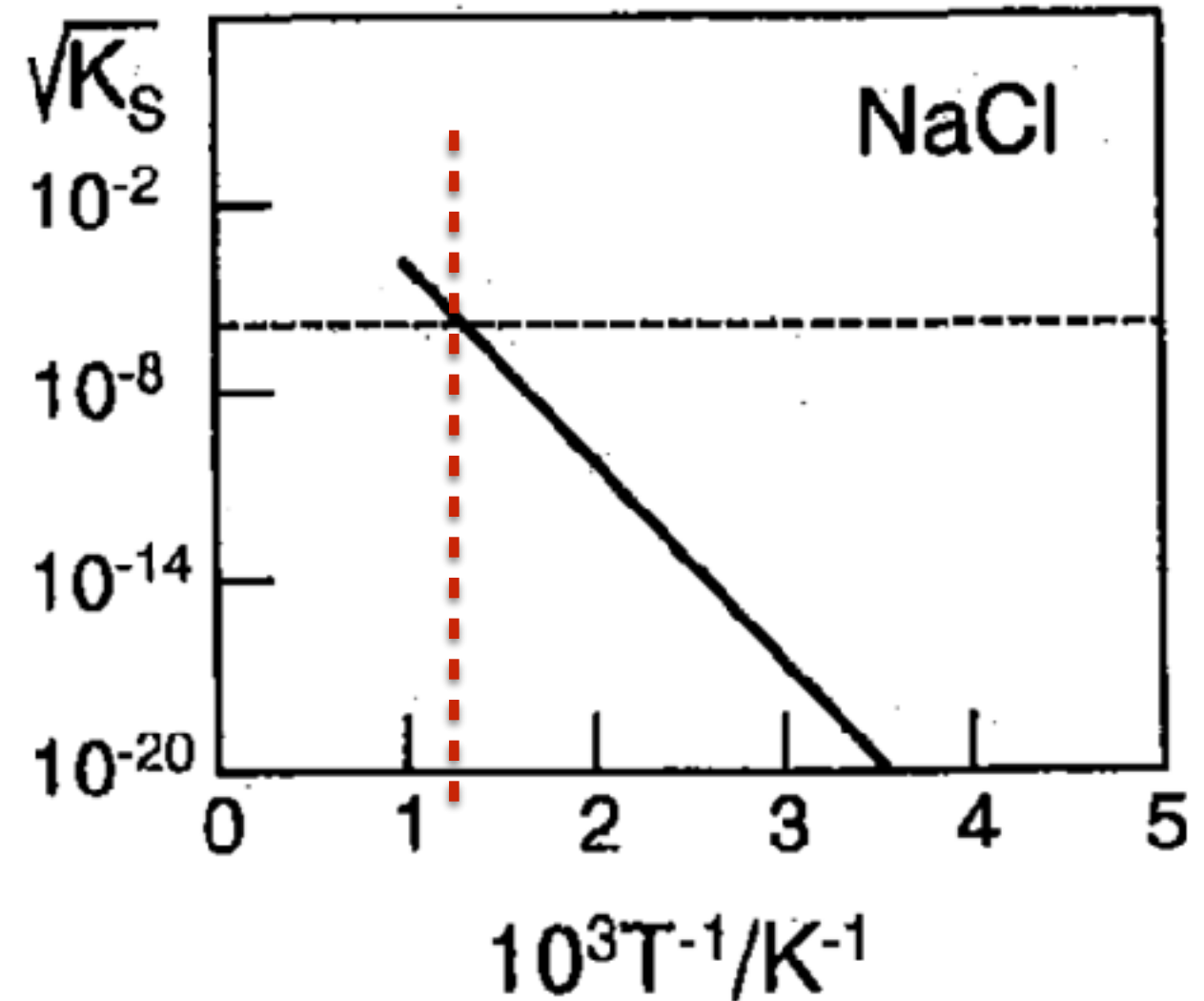
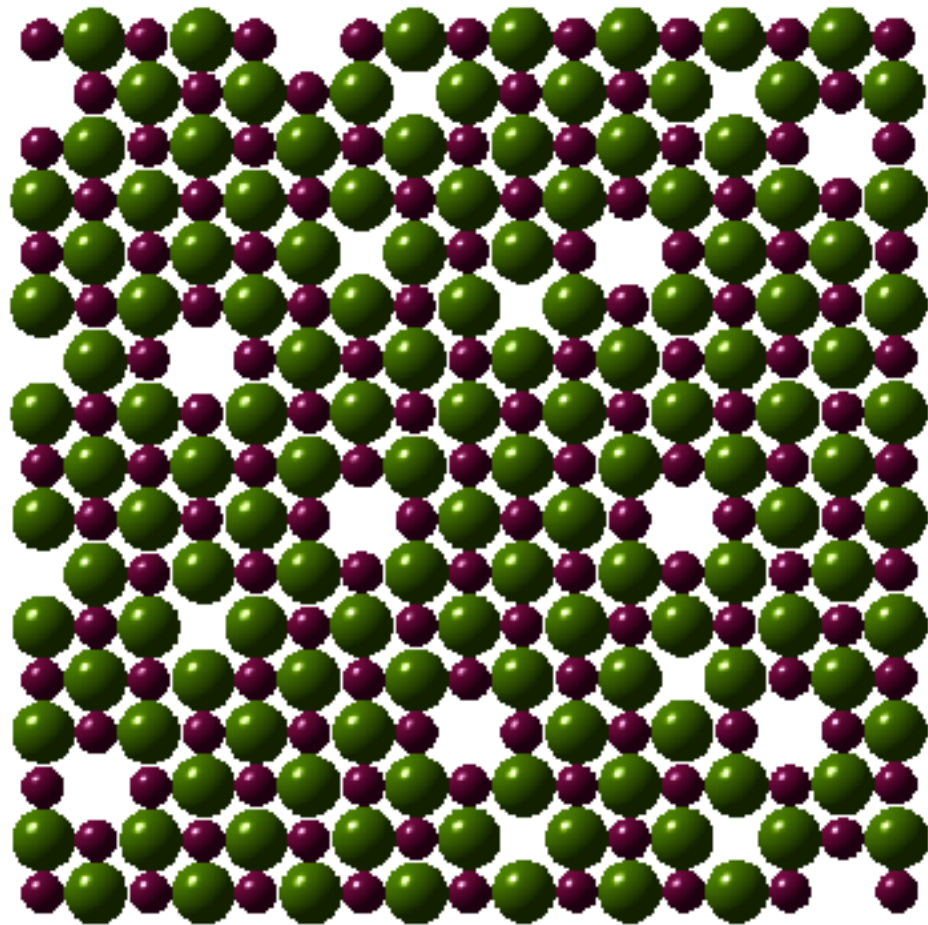


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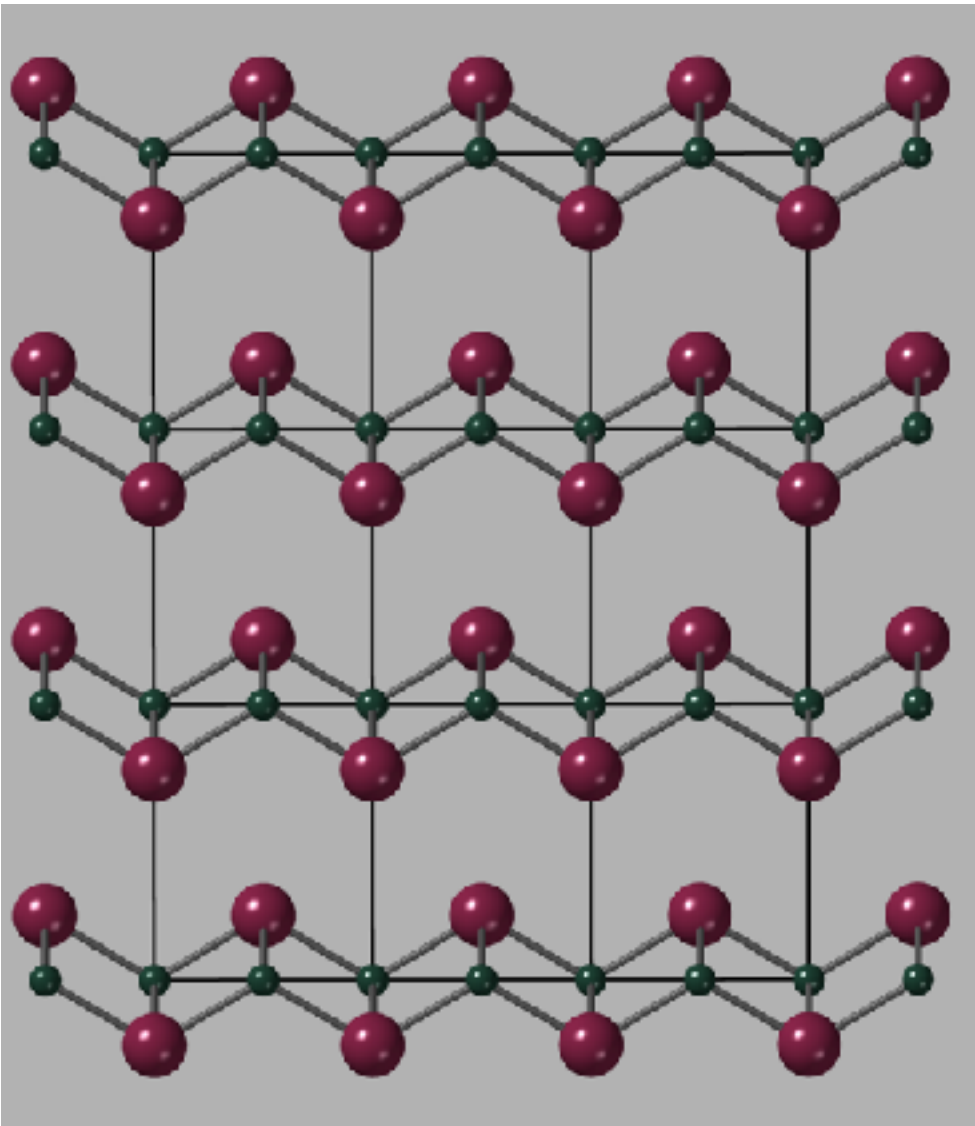
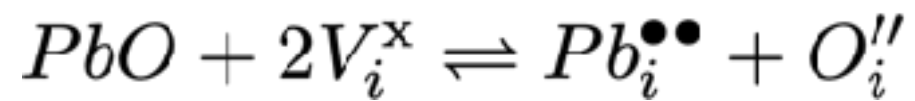
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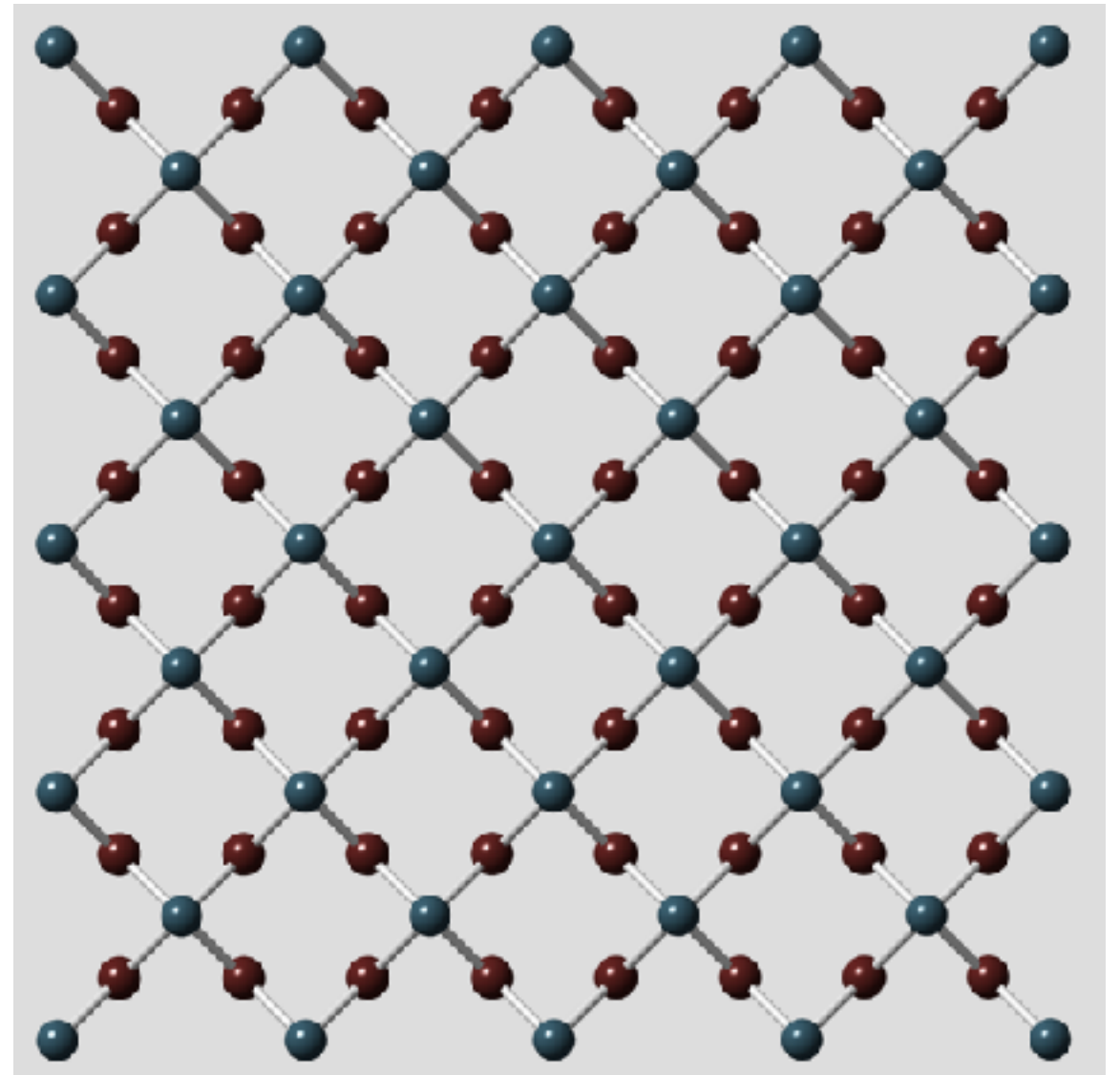
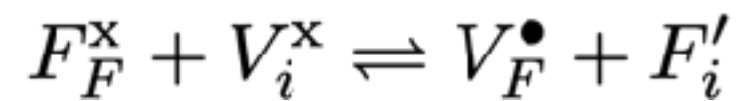
$$\Delta H_S^0 \approx 240 \text{ kJ.mol}^{-1}$$

Other stoichiometric internal reactions

Anti-Schottky



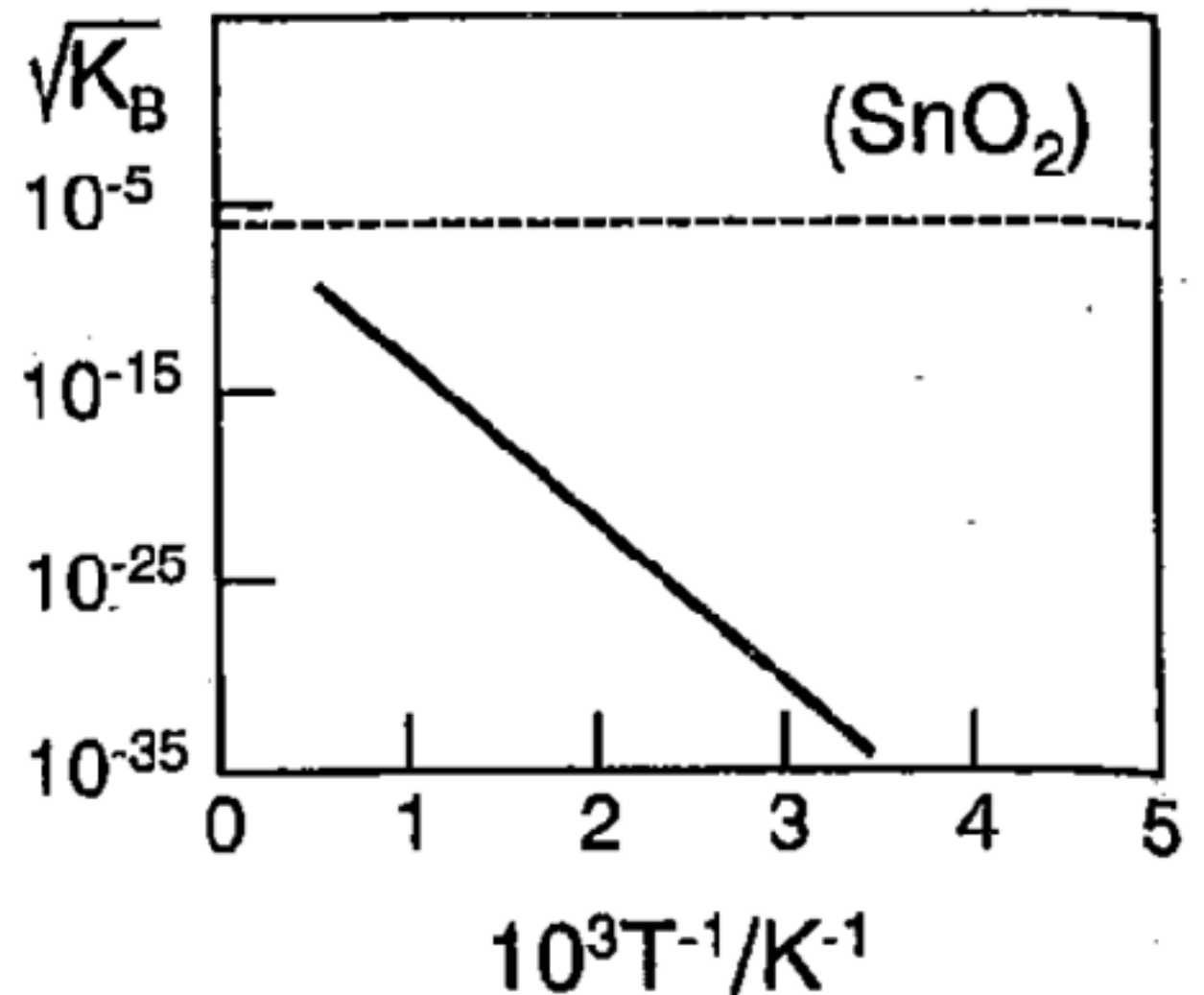
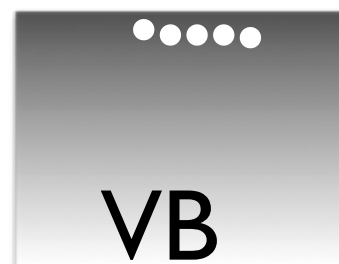
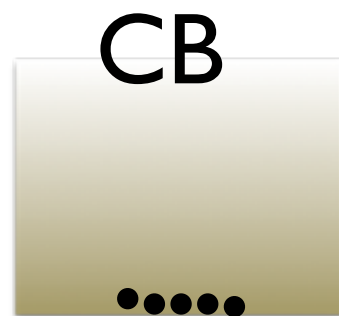
Anion Frenkel



Electronic defects

Band-to-band: $e_{\text{VB}}^{\times} + h_{\text{CB}}^{\times} \rightleftharpoons h_{\text{VB}}^{\bullet} + e_{\text{CB}}'$

electroneutrality: $[e'] = [h^{\bullet}] = \sqrt{K_B(T)} \times N_c N_v$



Internal Defect Reactions - MX

Defect creation processes occurring due to non-zero T without involvement of neighboring phases

Example Materials	Defect Rxn	Kroger-Vink Notation
AgCl	Frenkel (F)	$Ag_{Ag}^x + V_i^x \rightleftharpoons Ag_i^\bullet + V'_{Ag}$
NaCl	Schottky (S)	$Na_{Na}^x + Cl_{Cl}^x \rightleftharpoons V_{Cl}^\bullet + V'_{Na} + NaCl$
CsF	Anion-Frenkel (\bar{F})	$F_F^x + V_i^x \rightleftharpoons V_F^\bullet + F'_i$
PbO	Anti-Schottky (\bar{S})	$PbO + 2V_i^x \rightleftharpoons Pb_i^{\bullet\bullet} + O_i^{''}$
All	Band-Band (B)	$Nil \rightleftharpoons h^\bullet + e'$

Internal Defect Reactions - MX

Defect creation processes occurring due to non-zero T without involvement of neighboring phases

Example Materials	Defect Rxn	Kroger-Vink Notation
AgCl	Frenkel (F)	$Ag_{Ag}^x + V_i^x \rightleftharpoons Ag_i^\bullet + V'_{Ag}$
NaCl	Schottky (S)	$Na_{Na}^x + Cl_{Cl}^x \rightleftharpoons V_{Cl}^\bullet + V'_{Na} + NaCl$
CsF	Anion-Frenkel (\bar{F})	$F_F^x + V_i^x \rightleftharpoons V_F^\bullet + F'_i$
PbO	Anti-Schottky (\bar{S})	$PbO + 2V_i^x \rightleftharpoons Pb_i^{\bullet\bullet} + O_i^{''}$
All	Band-Band (B)	$Nil \rightleftharpoons h^\bullet + e'$

Acid-base

Redox

Extrinsic defect incorporation

Extrinsic defect incorporation

Doping

Alloying

Extrinsic defect incorporation

```
graph TD; A[Extrinsic defect incorporation] --> B[Doping]; A --> C[Alloying]; A --> D[Interstitial]; D --> E["C in Fe<br/>O2 in UO2"];
```

Doping

Alloying

Interstitial

C in Fe
O₂ in UO₂

Extrinsic defect incorporation

```
graph TD; A[Extrinsic defect incorporation] --> B[Substitutional]; A --> C[Doping]; A --> D[Alloying]; A --> E[Interstitial]; E --> F["C in Fe<br/>O2 in UO2"]
```

Substitutional

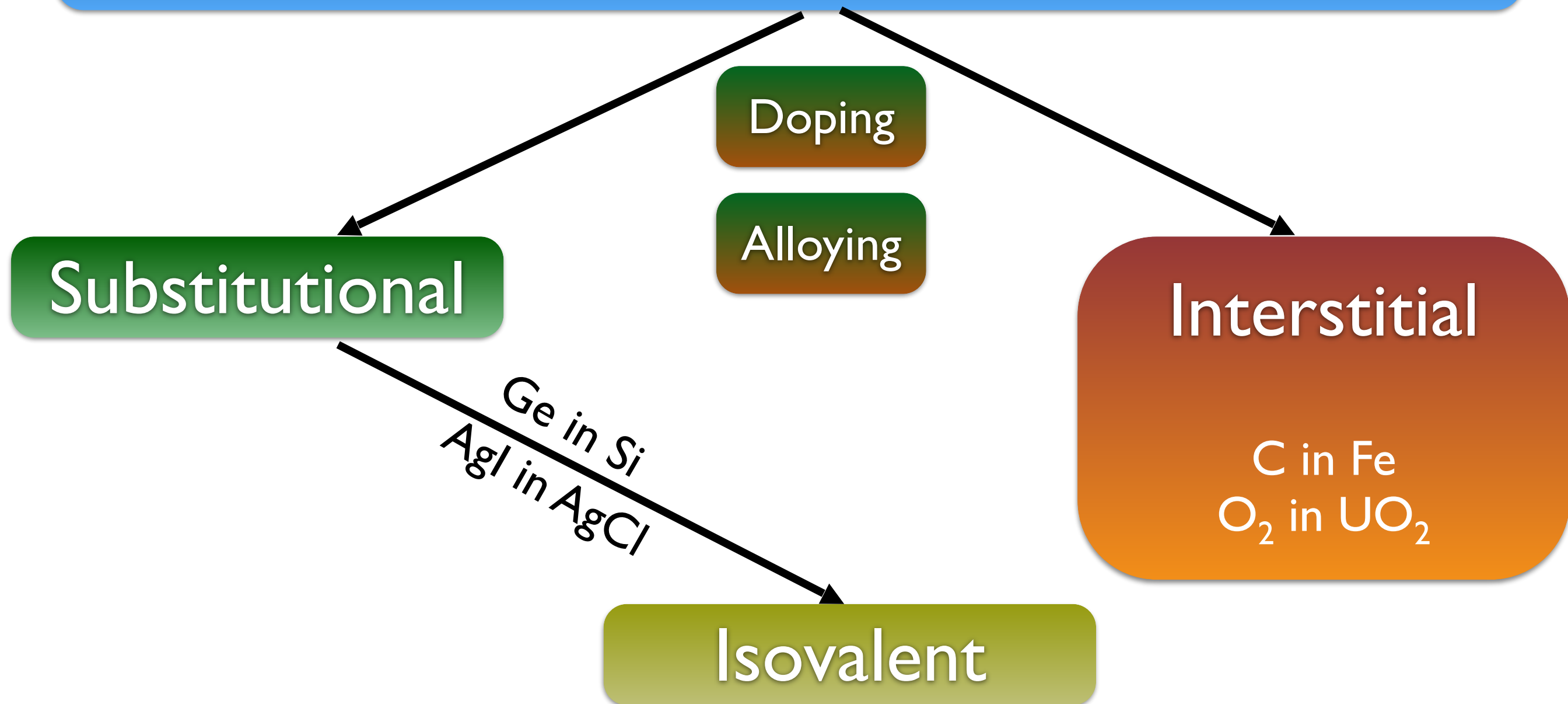
Doping

Alloying

Interstitial

C in Fe
O₂ in UO₂

Extrinsic defect incorporation



Extrinsic defect incorporation

Doping

Alloying

Substitutional

Interstitial

C in Fe
O₂ in UO₂

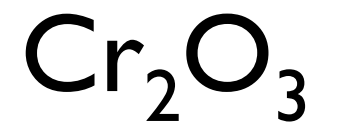
Isovalent

Aliovalent

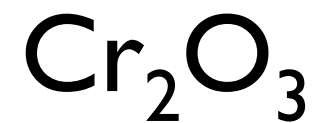
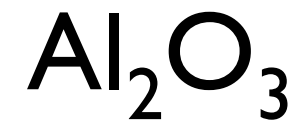
Ge in Si
AgI in AgCl

P in Si
CdCl₂ in AgCl

Example - Isovalent Substitutional

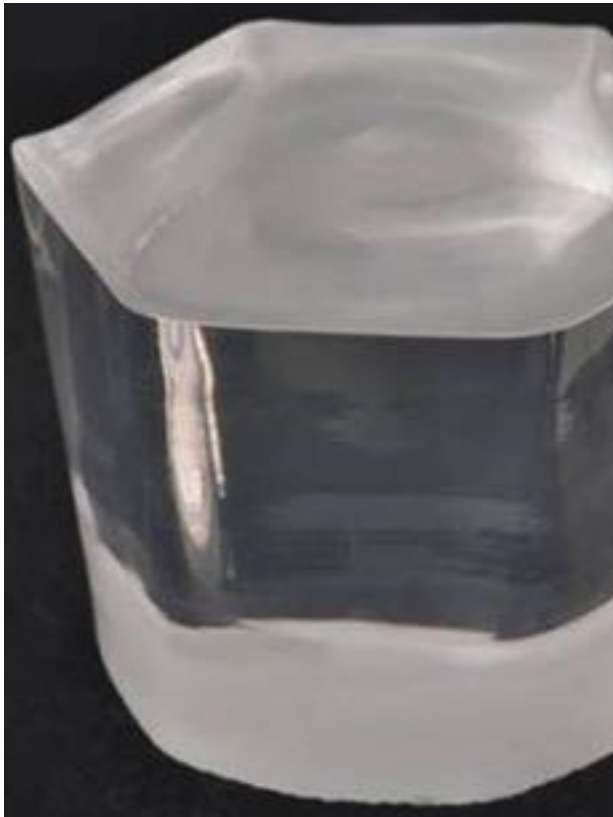
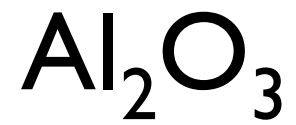


Example - Isovalent Substitutional

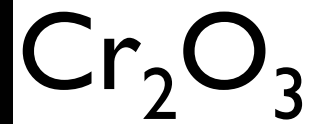


Increasing Cr_2O_3 →

Example - Isovalent Substitutional



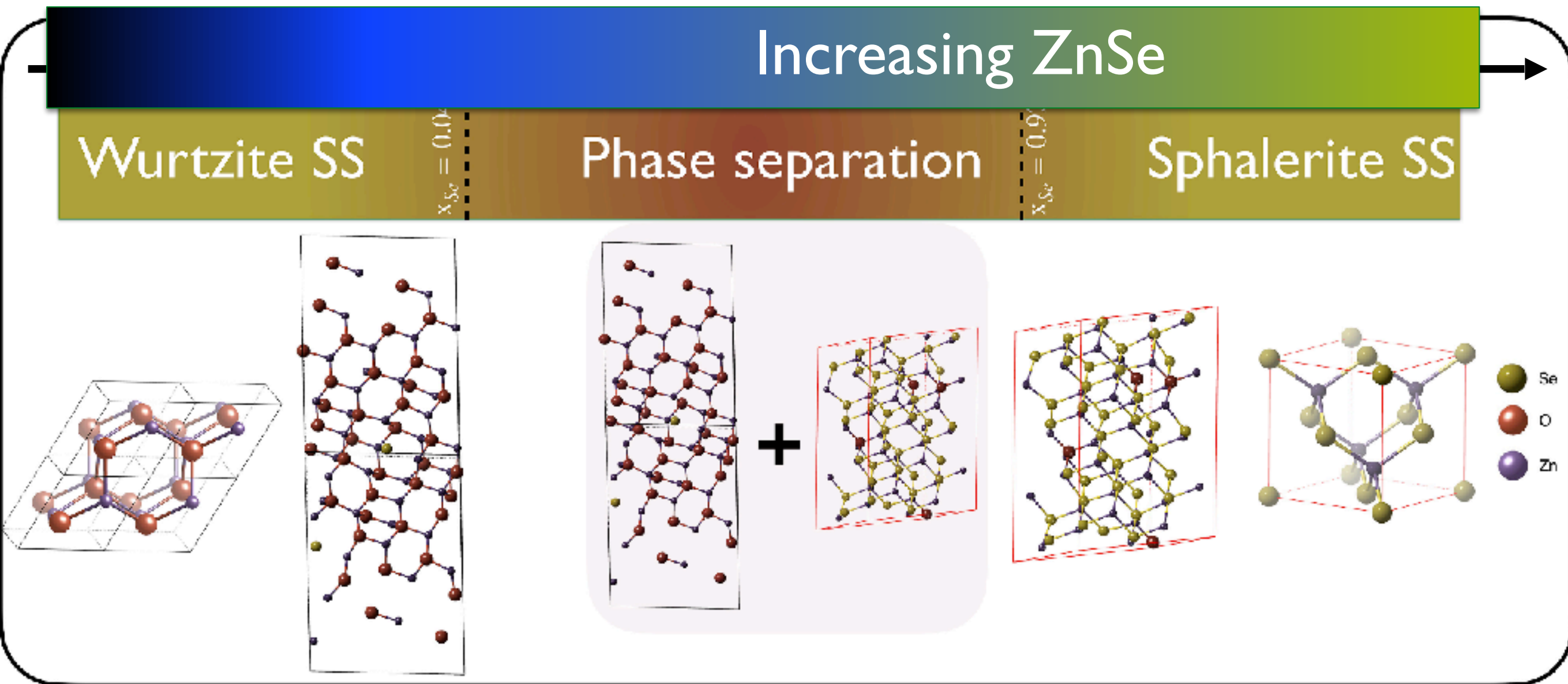
Ruby



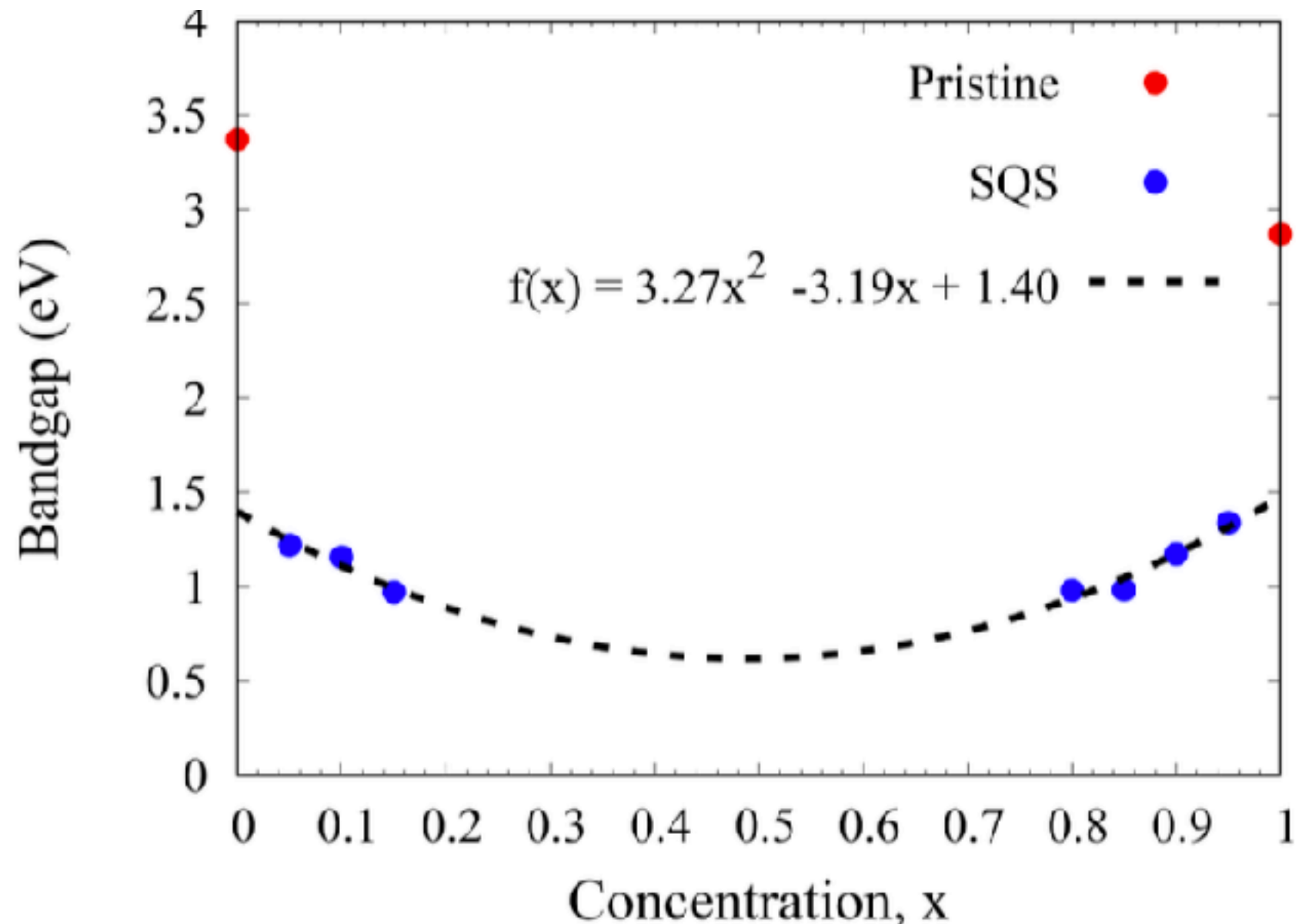
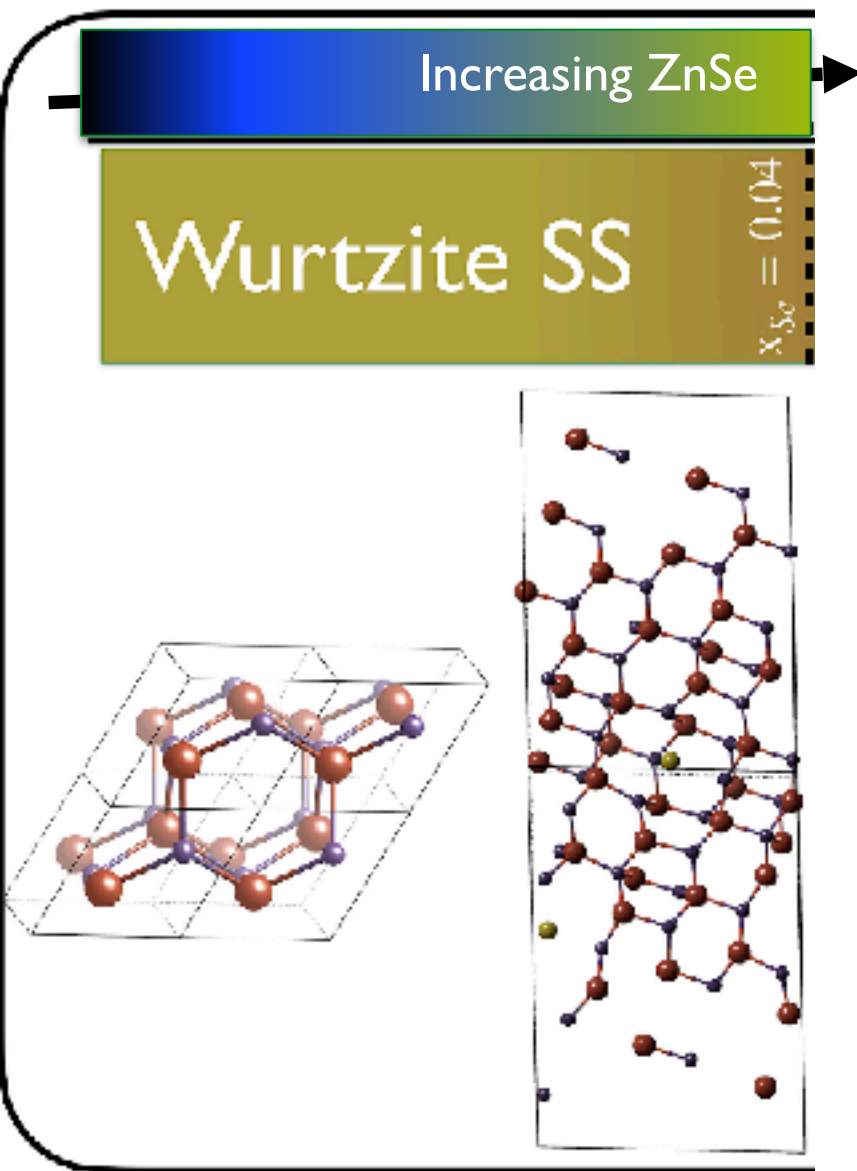
Increasing Cr_2O_3



Example - Isovalent Substitutional



Example - Isovalent Substitutional



Aliovalent Incorporation



Atoms with different valence than the site



Electro-neutrality

Aliovalent Incorporation



Atoms with different valence than the site



Electro-neutrality



Ionic
Compensation

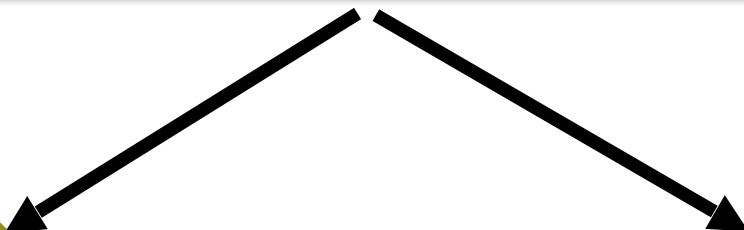
Aliovalent Incorporation



Atoms with different valence than the site



Electro-neutrality



Ionic
Compensation

Electronic
Compensation

Class Test 3

(10 marks)

AgCl crystallizes in the cF lattice with a lattice parameter of 0.5622 nm. Cl forms the ccp framework with Ag in the octahedral interstices.

Defect	Formation enthalpy (kJ.mol ⁻¹)	Formation entropy (kJ.mol ⁻¹)
Schottky	400	9.8R
Frenkel	140	9.4R

Determine the volume of AgCl at room temperature ($T = 300\text{ K}$) when you will find a single chlorine vacancy in the material.

Defect Reactions - Rules

- *Site relation:*

- The number of M sites in a compound M_aX_b must always be in correct proportion to the number of X sites
- Total number of each type of site may change

- *Site creation:*

- Must not affect the site relation described in rule above

- *Mass balance:*

- Mass balance must be maintained as in any chemical reaction

Note: subscript in the defect symbol indicates the site under consideration and is of no significance for the mass balance

- *Electroneutrality:*

- The crystal must remain electrically neutral
- Only neutral atoms or molecules are exchanged with other phases outside the crystal under consideration; within the crystal neutral particles can yield two or more oppositely charged defects

- *Surface sites:*

- Atom M displaced from the bulk to surface increases the number of M sites

Aliovalent Incorporation



Atoms with different valence than the site



Electro-neutrality

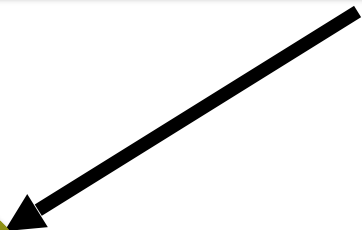
Aliovalent Incorporation



Atoms with different valence than the site



Electro-neutrality



Ionic
Compensation

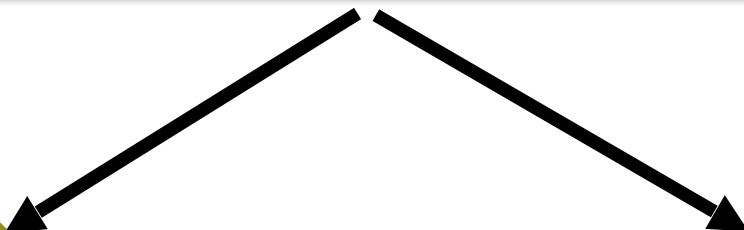
Aliovalent Incorporation



Atoms with different valence than the site



Electro-neutrality

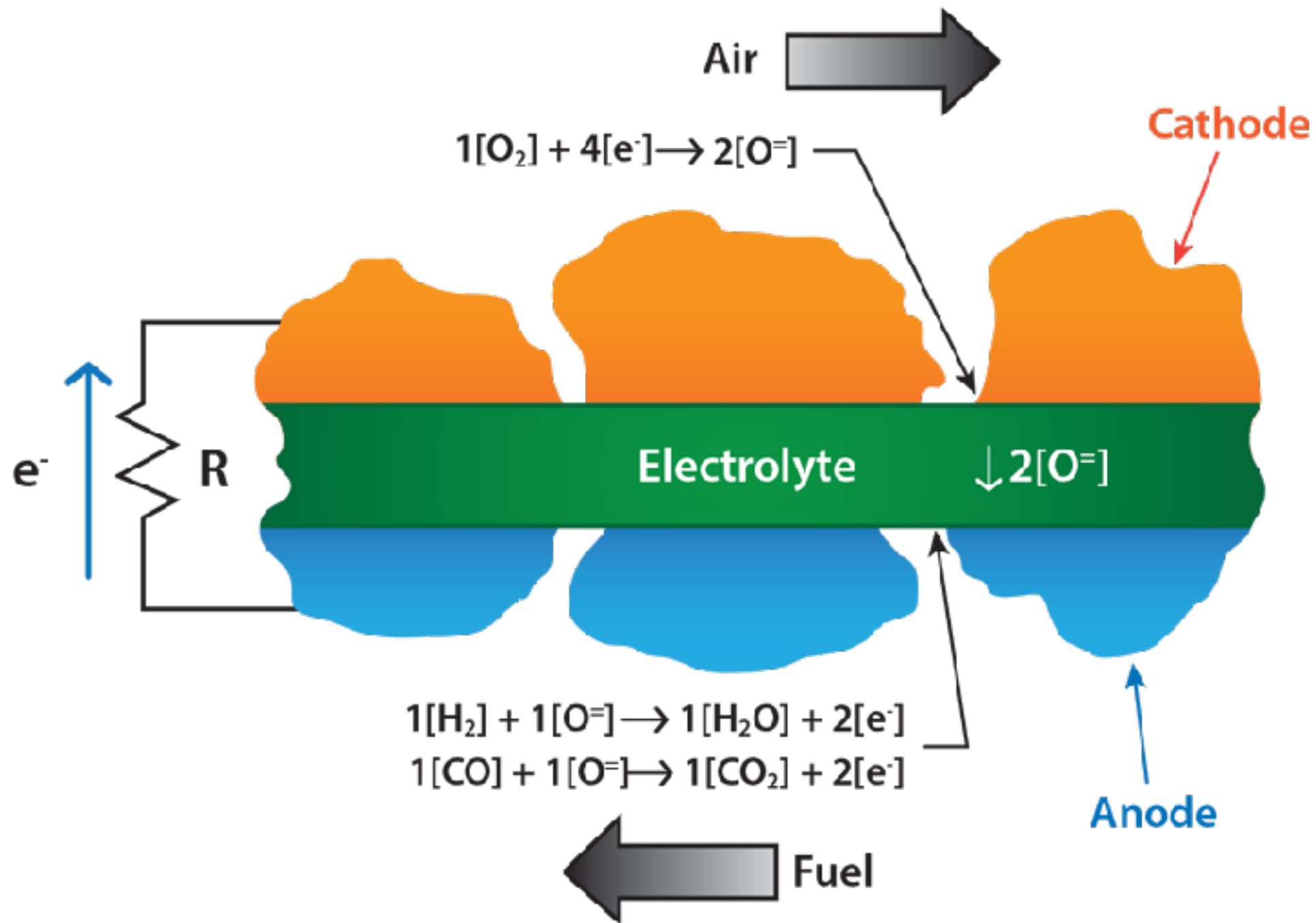


Ionic
Compensation

Electronic
Compensation

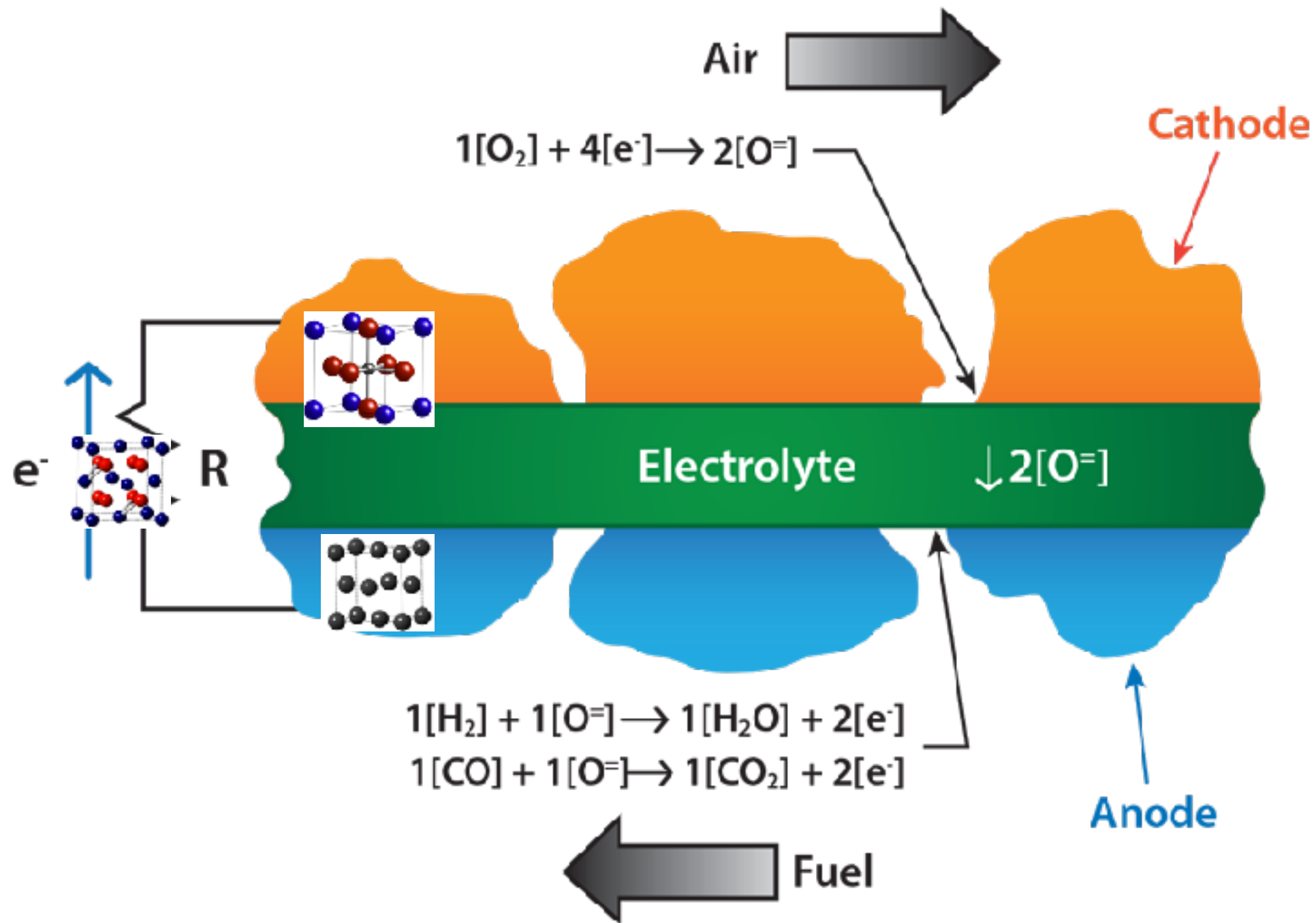
Anion Vacancies

Solid Oxide Fuel Cell electrolyte



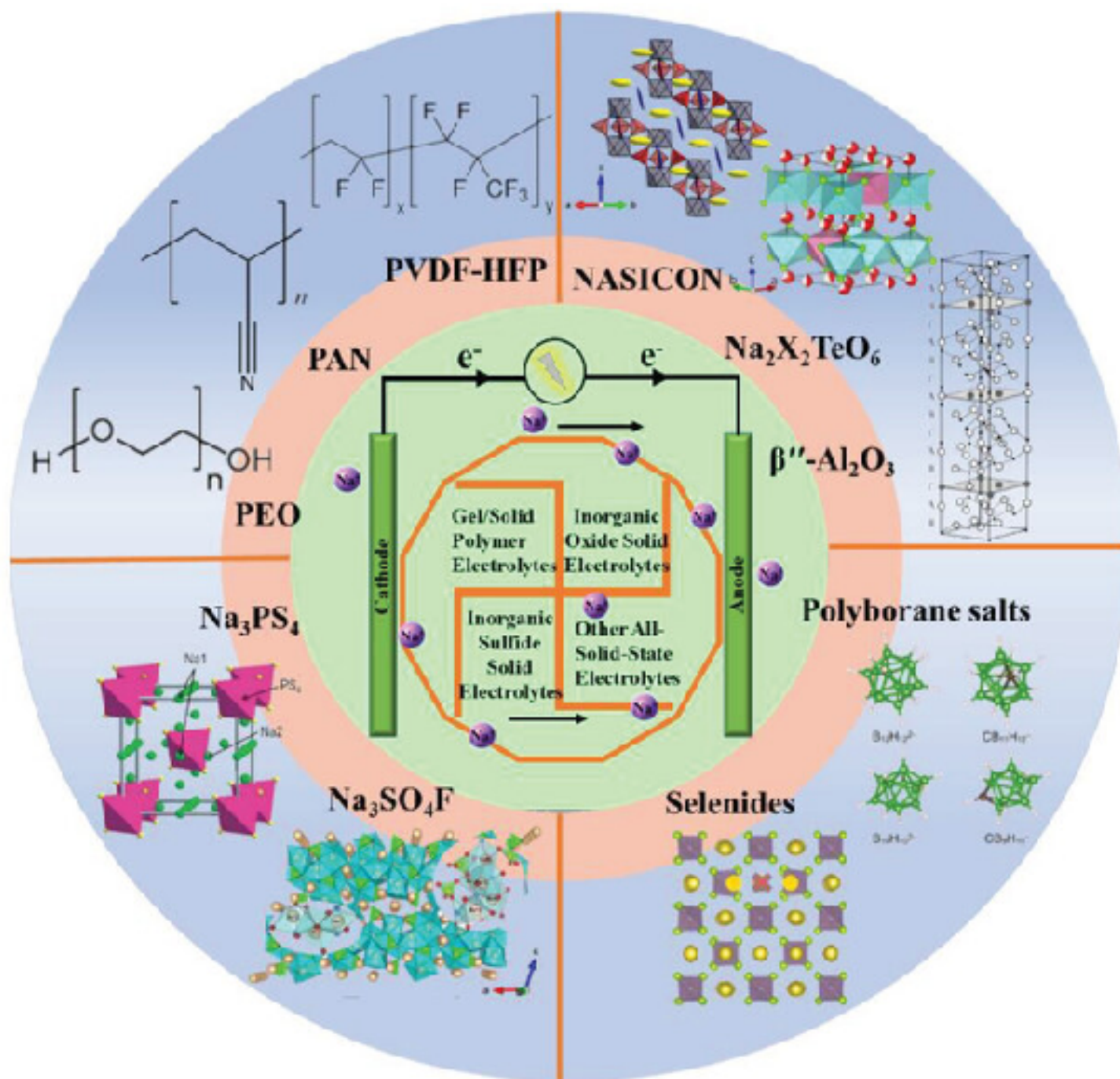
Anion Vacancies

Solid Oxide Fuel Cell electrolyte



Cation Interstitials

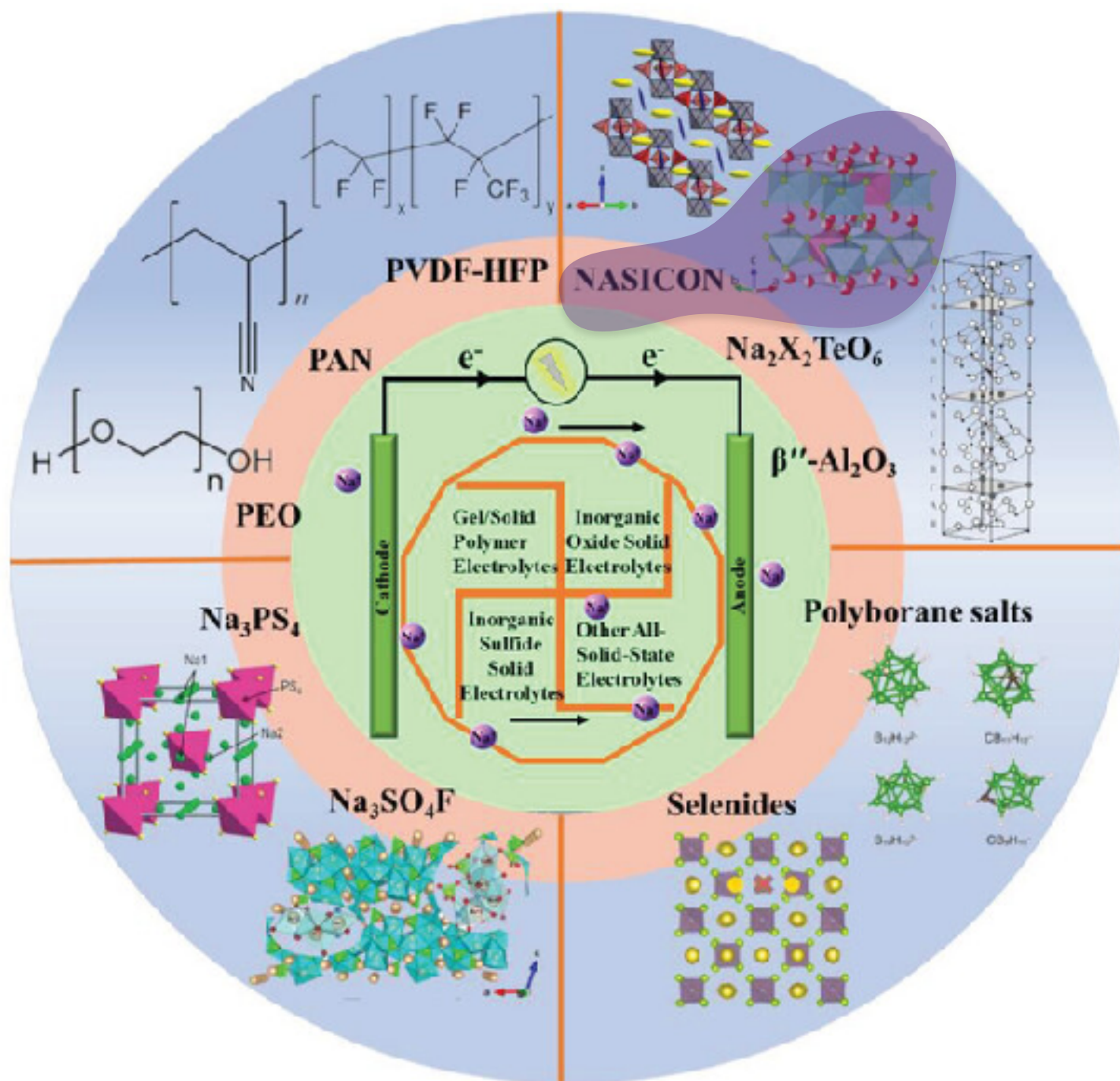
Solid electrolytes for Na-ion Batteries



Cation Interstitials

Solid electrolytes for Na-ion Batteries

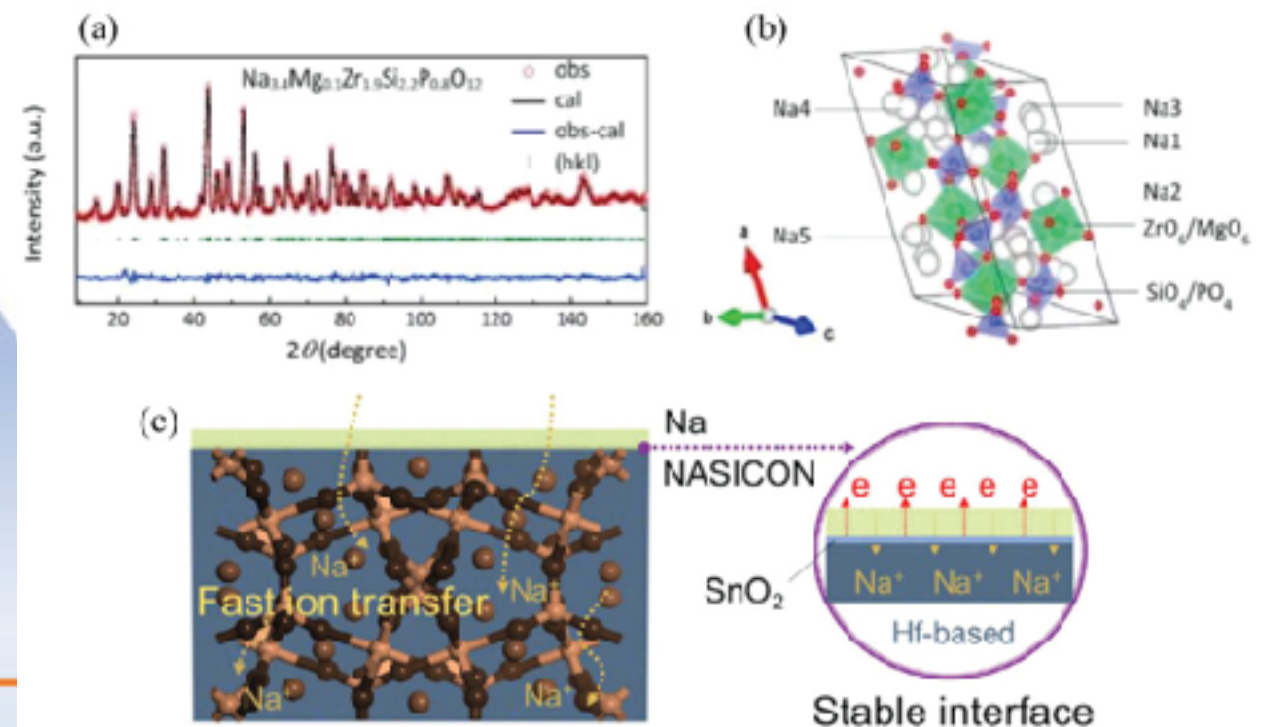
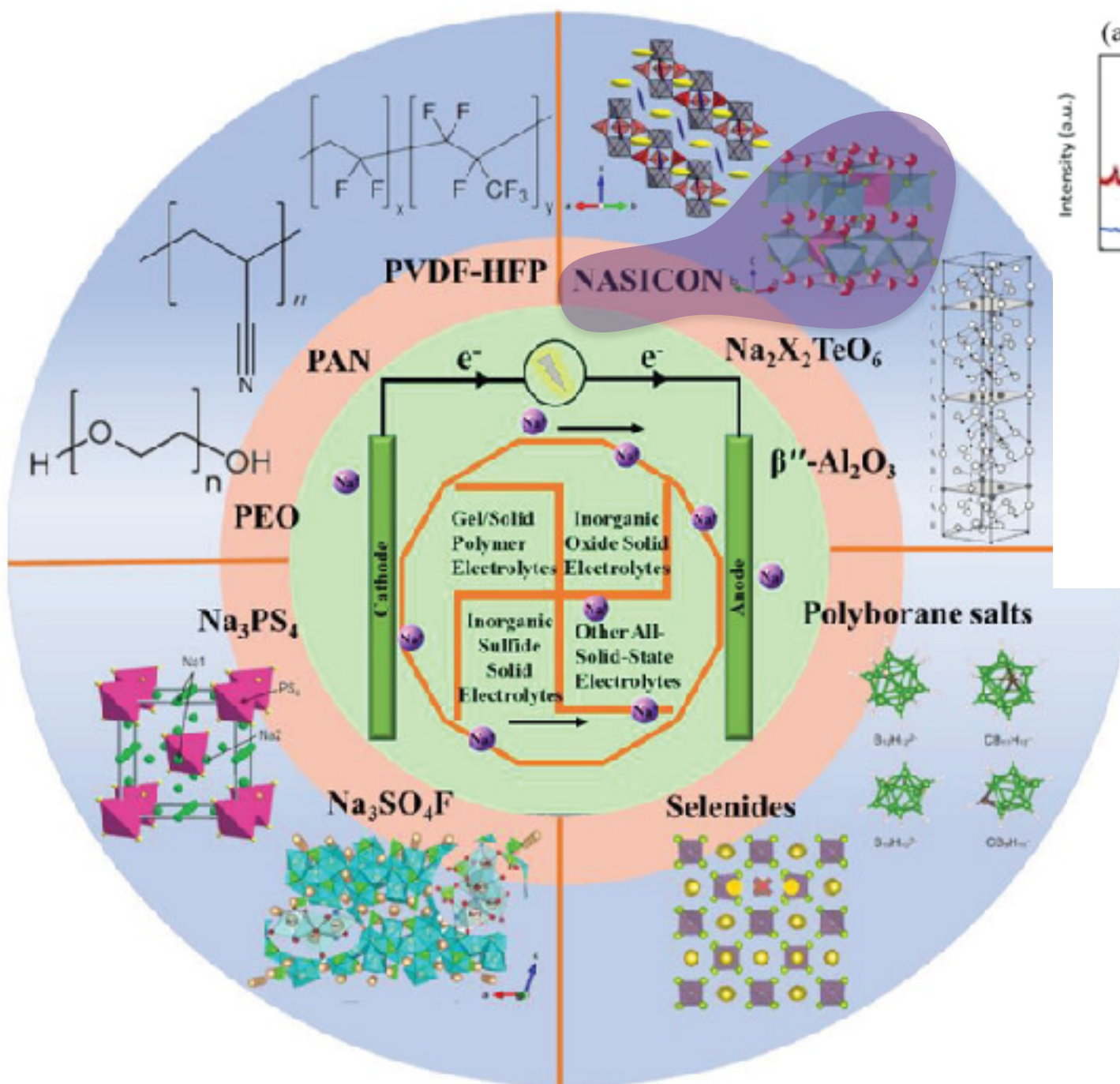
Sodium(**Na**) Super-Ionic (**SI**) Conductor (**Con**)



Cation Interstitials

Solid electrolytes for Na-ion Batteries

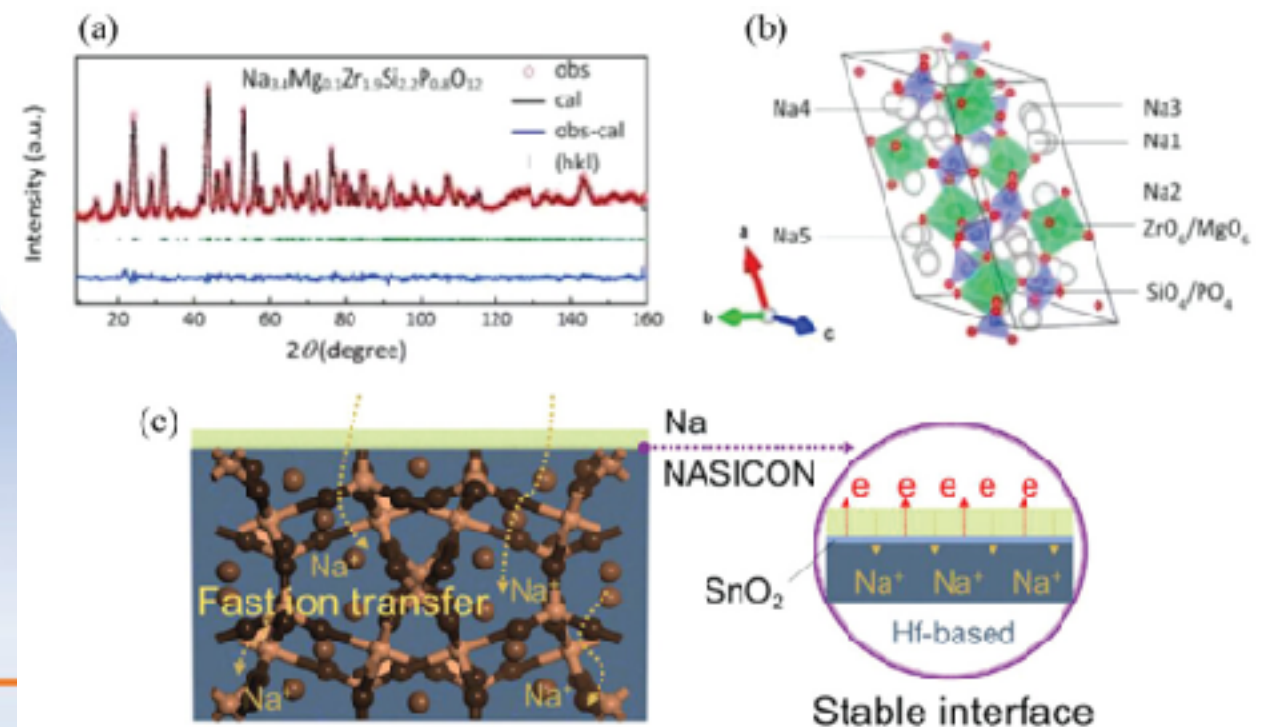
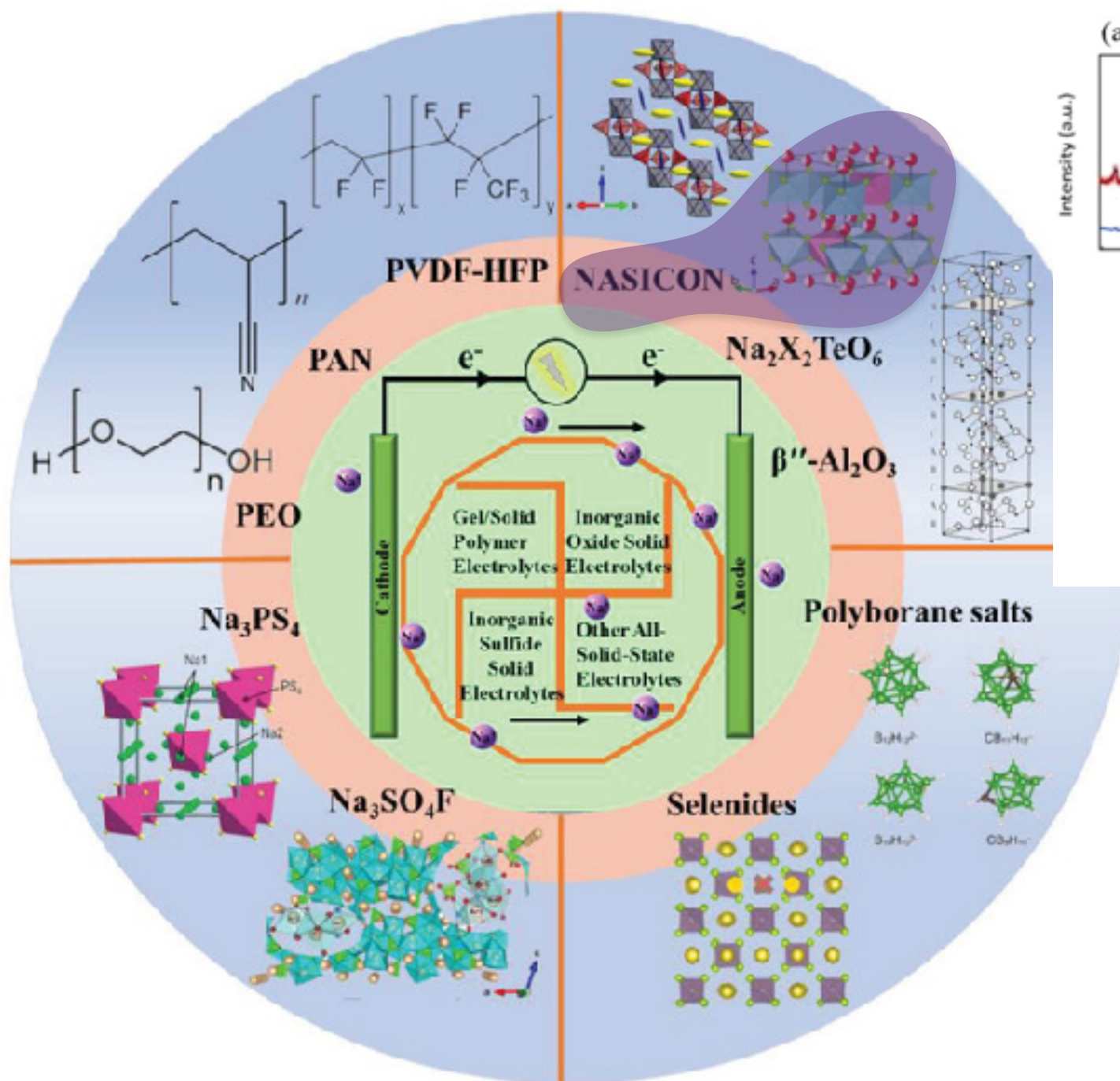
Sodium(**Na**) Super-Ionic (**SI**) Conductor (**Con**)



Cation Interstitials

Solid electrolytes for Na-ion Batteries

Sodium(**Na**) Super-Ionic (**SI**) Conductor (**Con**)

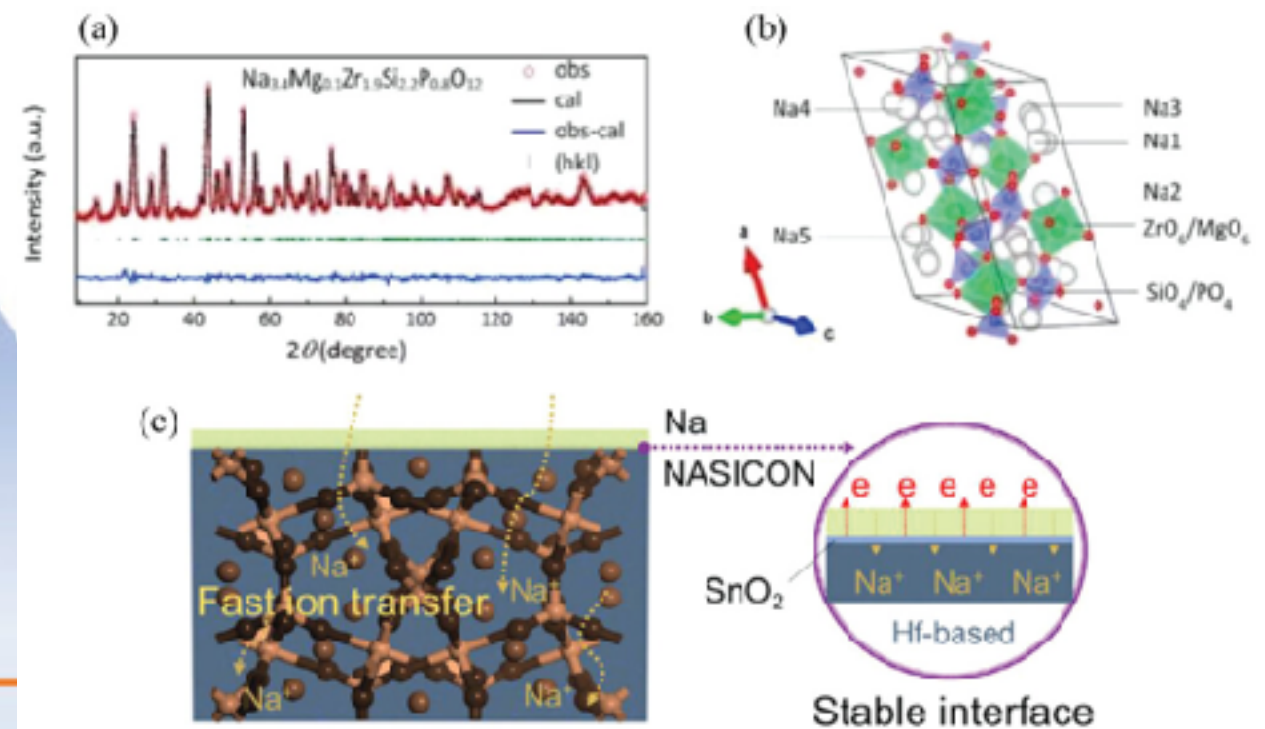
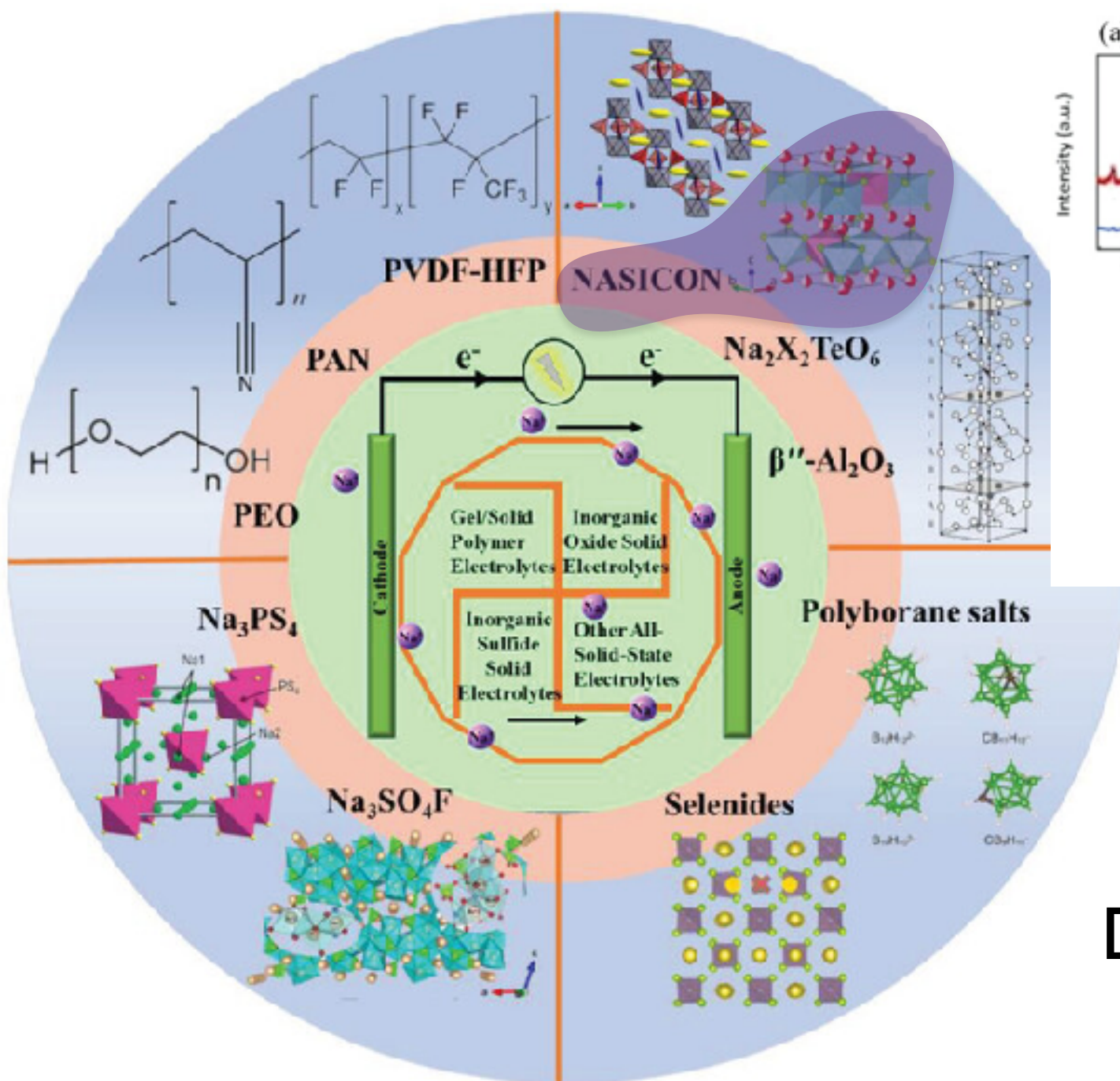


Host Material: $\text{NaZr}_2(\text{PO}_4)_3$

Cation Interstitials

Solid electrolytes for Na-ion Batteries

Sodium(**Na**) Super-Ionic (**SI**) Conductor (**Con**)

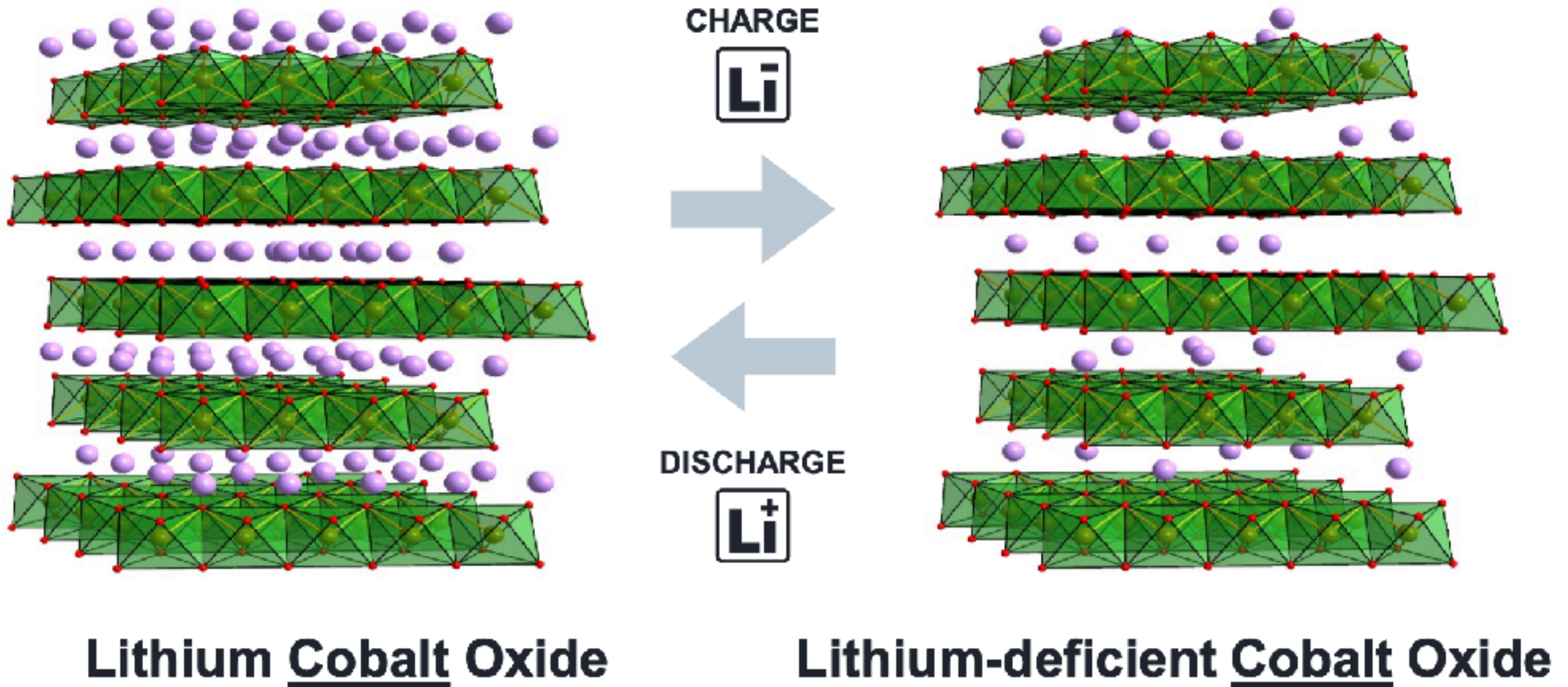


Host Material: $\text{NaZr}_2(\text{PO}_4)_3$

Dopant Material: $\text{Na}_4\text{Zr}_2(\text{SiO}_4)_3$

Electronic compensation

Li ion battery electrodes



Electronic compensation

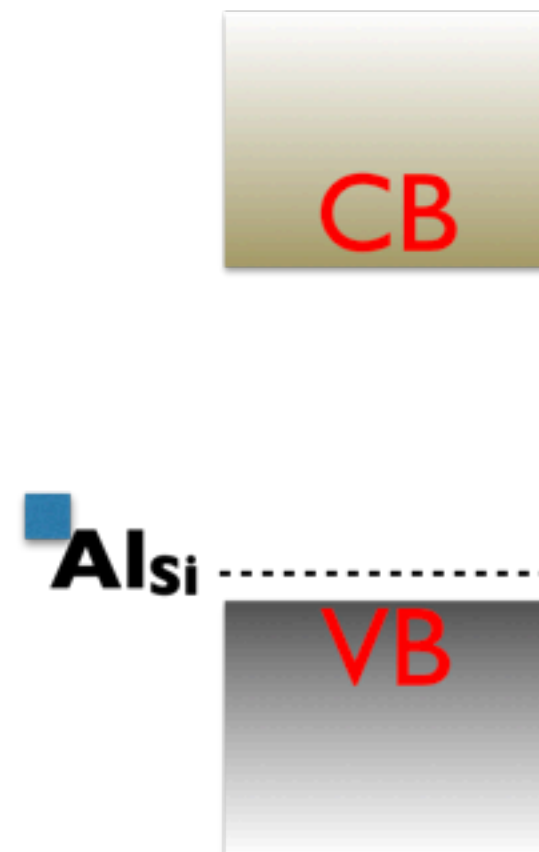
Solar Photovoltaic Absorber

Si \rightarrow Ne 3s² 3p²

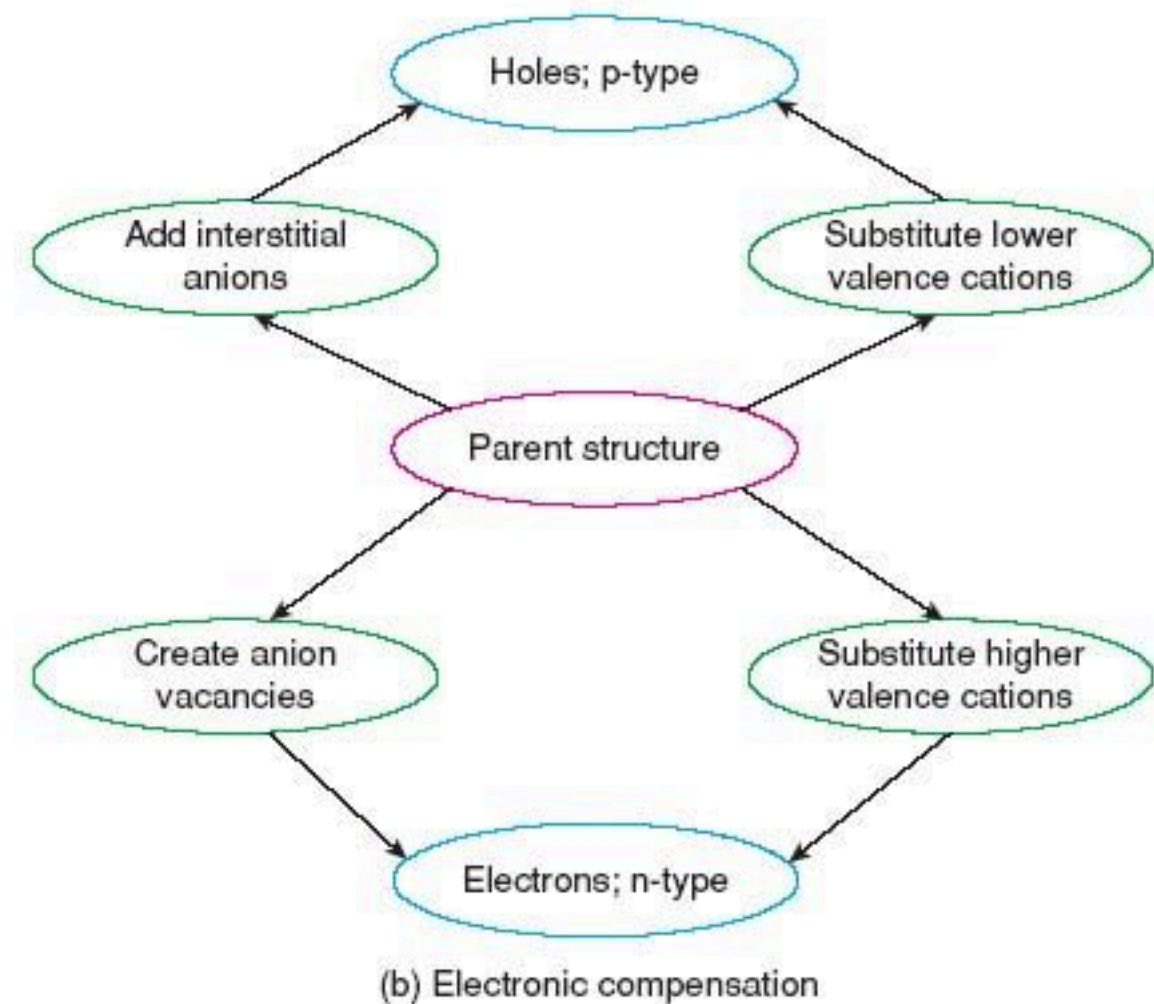
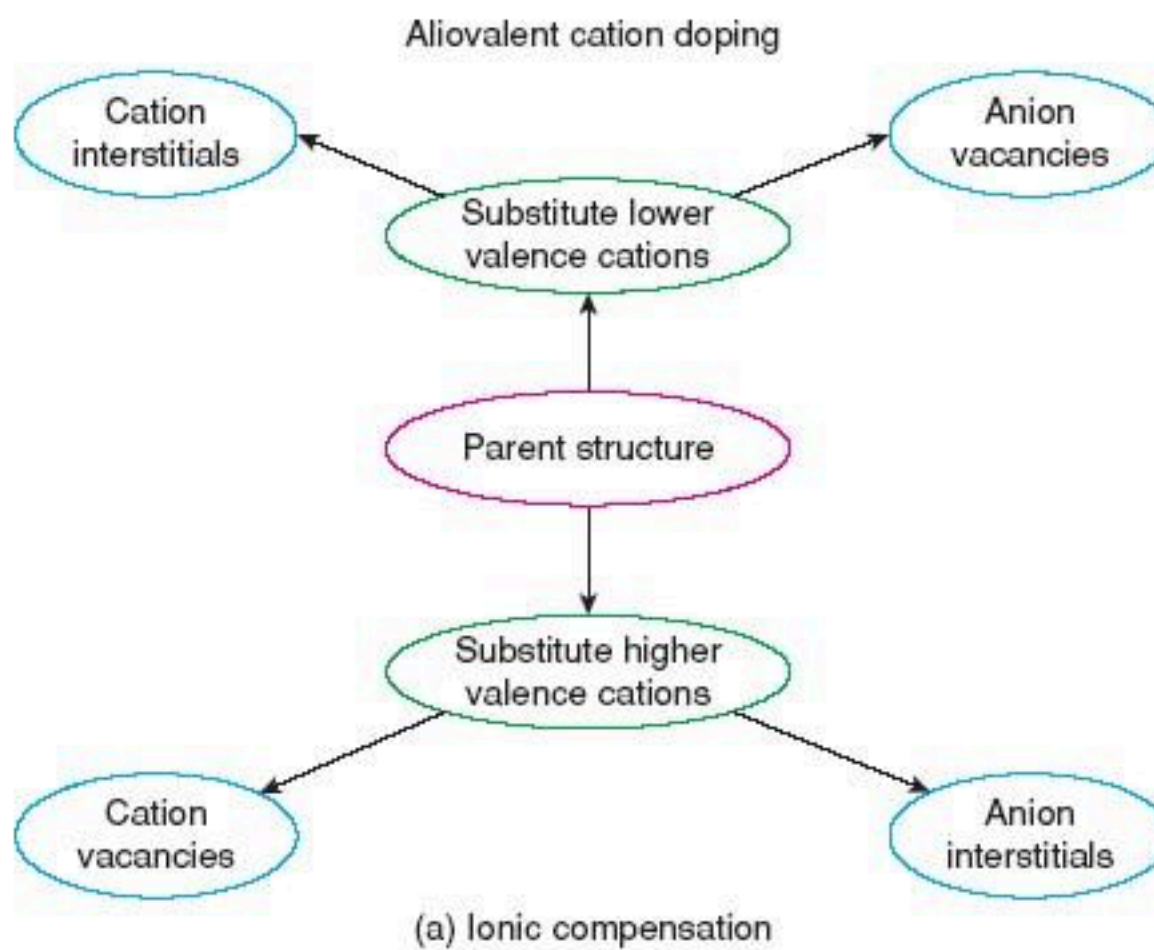
P \rightarrow Ne 3s² 3p³

Si \rightarrow Ne 3s² 3p²

Al \rightarrow Ne 3s² 3p¹

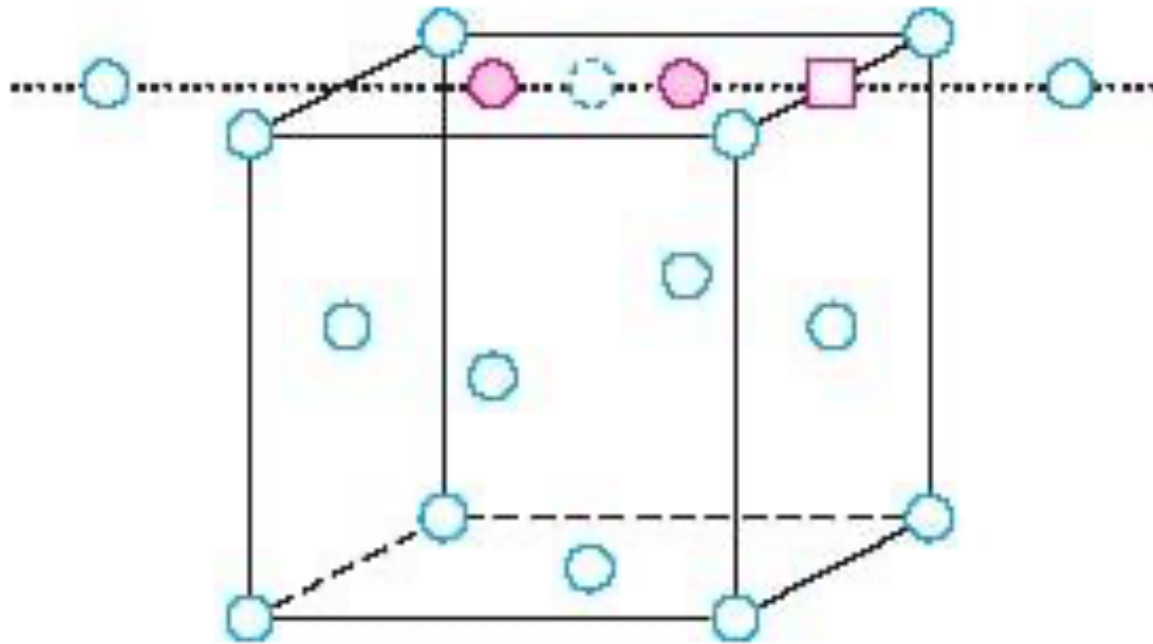


Summary

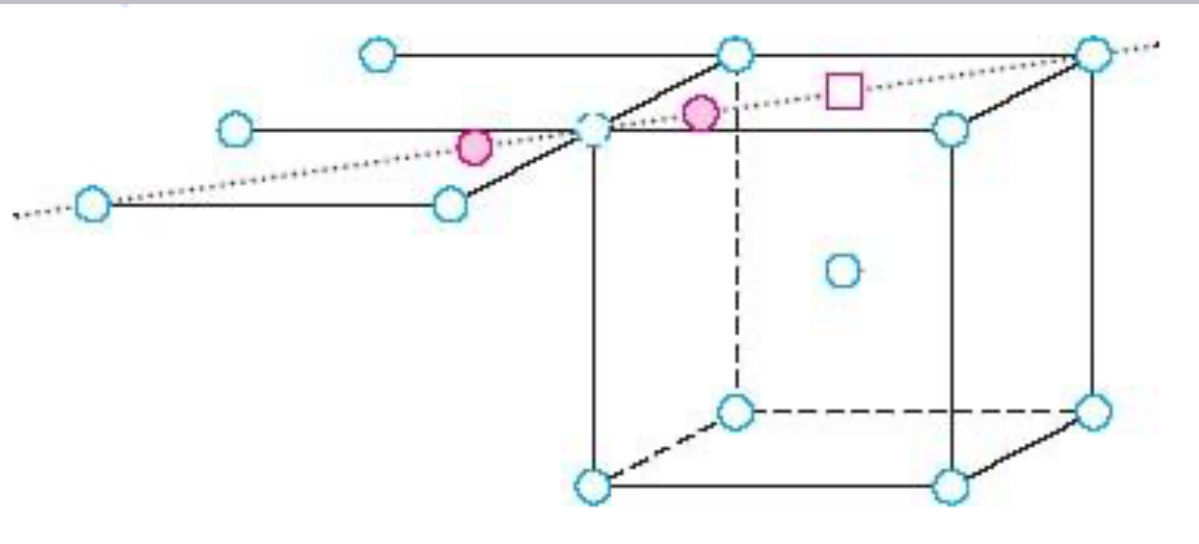


Read other examples in Section 2.3.3. of A.R. West

Defect Clusters

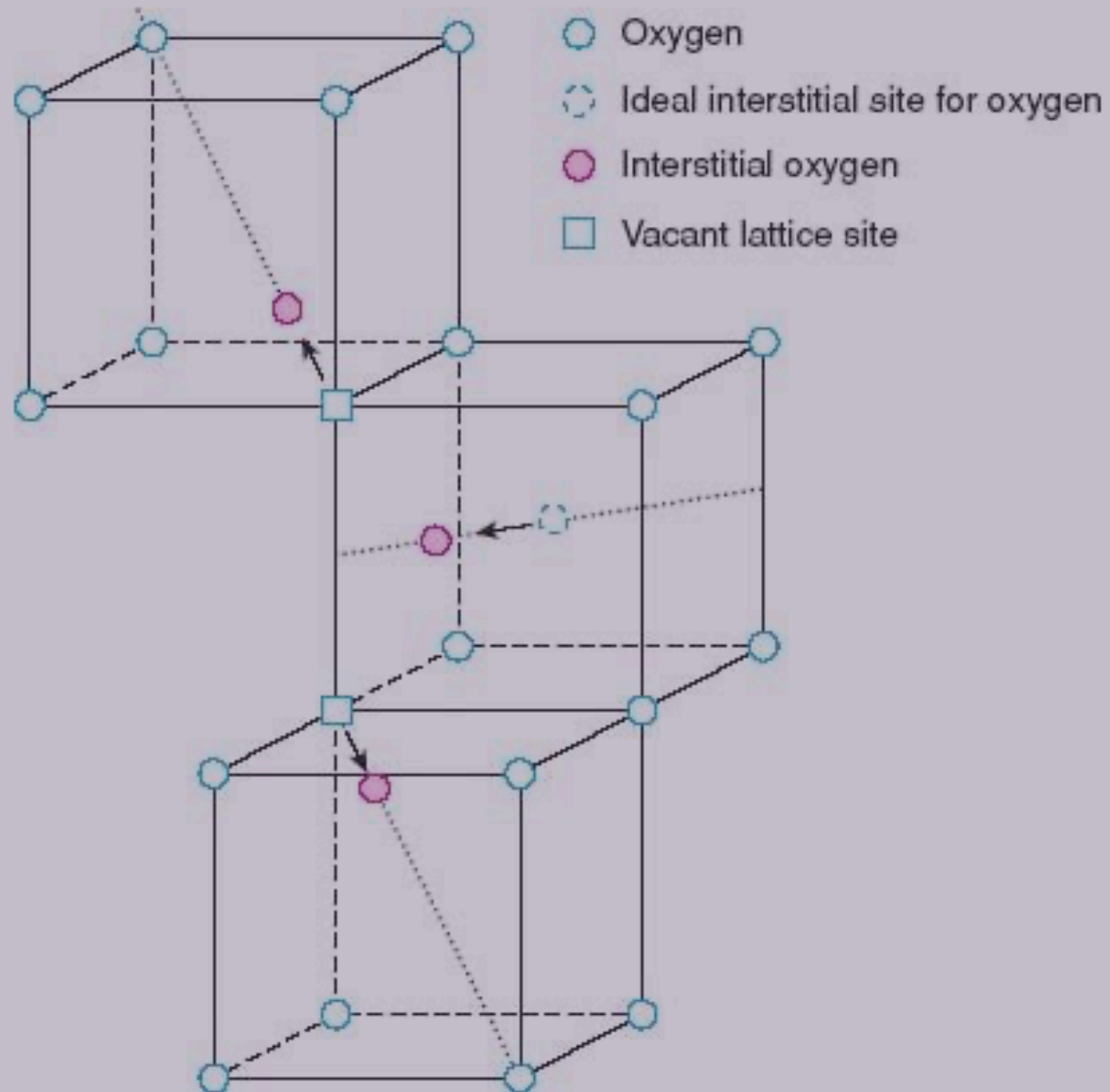


- Interstitial Pt atom at octahedral site in fcc Pt
- Displaced towards top face Pt atom
- Displaces top face Pt atom
- Two Pt atoms on distorted interstitial site - cluster



- Interstitial Fe atom at octahedral site in bcc Fe
- Displaced towards vertex Fe atom
- Displaces vertex Fe atom
- Two Fe atoms on distorted interstitial site - cluster

Defect Complexes in Oxides – UO_2



- UO_2 - ccp U^{4+} with O^{2-} in tetrahedral interstices
- Non-stoichiometry - UO_{2+x}
- Ideal interstitial site is the octahedral site
- Displaced along $\langle 110 \rangle$
- Displaces two other site O^{2-}
- 3 O_i on distorted interstitial sites + 2 V_O - cluster

Electronic properties of materials

- Concept of atomic and molecular orbitals, AO and MO
- MO to bands in crystalline solids - Tight binding, Free electron, and nearly free electron models
- Metals, semiconductors, insulators
- Electrical behaviour of metals and semiconductors
- **Section 3.3, 3.4, 8.1, 8.2, 8.4 in A.R. West**

Class Test 4

(10 marks)

Consider ZrO_2 doped with 5 mol% CaO . The oxygen vacancy concentration has the following dependencies on the p_{O_2} :

Low (**N**): $\propto p_{\text{O}_2}^{-\frac{1}{6}}$

Intermediate (**I**): $\propto p_{\text{O}_2}^0, \quad > > > \sqrt{K_S}$

High (**P**): $\propto p_{\text{O}_2}^{-\frac{1}{2}}$

Write down the appropriate Brouwer approximations that give such dependencies, and determine the pre-factors that make the proportionalities above into equalities.